

High Reliability Series Serial EEPROM Series

I²C BUS Serial EEPROMs



BR24L□□-W Series

BR24L01A-W, BR24L02-W, BR24L04-W, BR24L08-W,
BR24L16-W, BR24L32-W, BR24L64-W

BR24S□□□-W Series

BR24S16-W, BR24S32-W, BR24S64-W, BR24S128-W, BR24S256-W

ROHM's series of serial EEPROMs represent the highest level of reliability on the market. A double cell structure provides a failsafe method of data reliability, while a double reset function prevents data miswriting. In addition, gold pads and gold wires are used for internal connections, pushing the boundaries of reliability to the limit.

BR24L□□-W Series assort 1Kbit~64Kbit. BR24S□□□-W Series are possible to operate at high speed in low voltage and assort 16Kbit~256Kbit.

Contents

BR24L□□-W Series

BR24L01A-W, BR24L02-W, BR24L04-W, BR24L08-W,
BR24L16-W, BR24L32-W, BR24L64-W

• • • • P2

BR24S□□□-W Series

BR24S16-W, BR24S32-W, BR24S64-W,
BR24S128-W, BR24S256-W

• • • • P17

I²C BUS Serial EEPROMs

BR24L□□-W Series

BR24L01A-W, BR24L02-W, BR24L04-W, BR24L08-W,
BR24L16-W, BR24L32-W, BR24L64-W

●Description

BR24L□□-W series is a serial EEPROM of I²C BUS interface method.

●Features

- Completely conforming to the world standard I²C BUS. All controls available by 2 ports of serial clock(SCL) and serial data(SDA)
- Other devices than EEPROM can be connected to the same port, saving microcontroller port
- 1.8V~5.5V ^{*1} single power source action most suitable for battery use
- Page write mode useful for initial value write at factory shipment
- Highly reliable connection by Au pad and Au wire
- Auto erase and auto end function at data rewrite
- Low current consumption
 - At write operation (5V) : 1.2mA (Typ.) ^{*2}
 - At read operation (5V) : 0.2mA (Typ.)
 - At standby operation (5V) : 0.1μA (Typ.)
- Write mistake prevention function
 - Write (write protect) function added
 - Write mistake prevention function at low voltage
- SOP8/SOP-J8/SSOP-B8/TSSOP-B8/MSOP8/TSSOP-B8J/VSON008X2030 compact package ^{*3}
- Data rewrite up to 1,000,000 times
- Data kept for 40 years
- Noise filter built in SCL / SDA terminal
- Shipment data all address FFh

^{*1} BR24L02-W, BR24L16-W, BR24L32-W : 1.7~5.5V

^{*2} BR24L32-W, BR24L64-W : 1.5mA

^{*3} Refer to following list

Page write

Number of Pages	8Byte	16Byte	32Byte
Product number	BR24L01A-W BR24L02-W	BR24L04-W BR24L08-W BR24L16-W	BR24L32-W BR24L64-W

●BR24L series

Capacity	Bit format	Type	Power source Voltage	SOP8	SOP-J8	SSOP-B8	TSSOP-B8	MSOP8	TSSOP-B8J	VSON008 X2030
				F	FJ	FV	FVT	FVM	FVJ	NUX
1Kbit	128×8	BR24L01A-W	1.8~5.5V	●	●	●	●	●	●	●
2Kbit	256×8	BR24L02-W	1.7~5.5V	●	●	●	●	●	●	●
4Kbit	512×8	BR24L04-W	1.8~5.5V	●	●	●	●	●	●	●
8Kbit	1K×8	BR24L08-W	1.8~5.5V	●	●	●	●	●	●	●
16Kbit	2K×8	BR24L16-W	1.7~5.5V	●	●	●	●	●	●	
32Kbit	4K×8	BR24L32-W	1.7~5.5V	●	●	●	●			
64Kbit	8K×8	BR24L64-W	1.8~5.5V	●	●					

●Absolute maximum ratings (Ta=25°C)

Parameter	symbol	Limits	Unit
Impressed voltage	V _{CC}	-0.3~+6.5	V
Permissible dissipation	Pd	450 (SOP8) ^{*1}	mW
		450 (SOP-J8) ^{*2}	
		300 (SSOP-B8) ^{*3}	
		330 (TSSOP-B8) ^{*4}	
		310 (MSOP8) ^{*5}	
		310 (TSSOP-B8J) ^{*6}	
		300 (VSON008X2030) ^{*7}	
Storage temperature range	Tstg	-65~+125	°C
Action temperature range	Topr	-40~+85	°C
Terminal voltage	—	-0.3~V _{CC} +1.0	V

When using at Ta=25°C or higher, 4.5mW^(1,2), 3.0mW^(3,7)
3.3mW⁽⁴⁾, 3.1mW^(5,6) to be reduced per 1°C

●Memory cell characteristics (Ta=25°C, V_{CC}=1.8~5.5V) ^{*1}

Parameter	Limits			Unit
	Min.	Typ.	Max.	
Number of data rewrite times ^{*2}	1,000,000	—	—	Times
Data hold years ^{*2}	40	—	—	Years

OShipment data all address FFh ^{*1} BR24L02/16/32-W : 1.7~5.5V
^{*2} Not 100% TESTED

●Recommended operating conditions

Parameter	Symbol	Limits	Unit
Power source voltage	V _{CC}	1.8~5.5 ^{*1}	V
Input voltage	V _{IN}	0~V _{CC}	

^{*1} BR24L02/16/32-W : 1.7~5.5V

●Electrical characteristics (Unless otherwise specified, Ta=-40~+85°C, V_{CC}=1.8~5.5V) ^{*1}

Parameter	Symbol	Limits			Unit	Conditions
		Min.	Typ.	Max.		
"HIGH" input voltage 1	V _{IH1}	0.7V _{CC}	—	V _{CC} +1.0 ^{*2}	V	2.5≤V _{CC} ≤5.5V
"LOW" input voltage 1	V _{IL1}	-0.3 ^{*2}	—	0.3 V _{CC}	V	2.5≤V _{CC} ≤5.5V
"HIGH" input voltage 2	V _{IH2}	0.8V _{CC}	—	V _{CC} +1.0 ^{*2}	V	1.8≤V _{CC} <2.5V
"LOW" input voltage 2	V _{IL2}	-0.3 ^{*2}	—	0.2 V _{CC}	V	1.8≤V _{CC} <2.5V
"HIGH" input voltage 3 ^{*3}	V _{IH3}	0.8V _{CC}	—	V _{CC} +1.0	V	1.7≤V _{CC} <1.8V
"HIGH" input voltage 3 ^{*4}	V _{IH3}	0.9V _{CC}	—	V _{CC} +1.0	V	1.7≤V _{CC} <1.8V
"LOW" input voltage 3 ^{*2}	V _{IL3}	-0.3	—	0.1 V _{CC}	V	1.7≤V _{CC} <1.8V
"LOW" output voltage 1	V _{OL1}	—	—	0.4	V	I _{OL} =3.0mA, 2.5V≤V _{CC} ≤5.5V, (SDA)
"LOW" output voltage 2	V _{OL2}	—	—	0.2	V	I _{OL} =0.7mA, 1.7V≤V _{CC} <2.5V, (SDA)
Input leak current	I _{LI}	-1	—	1	μA	V _{IN} =0V~V _{CC}
Output leak current	I _{LO}	-1	—	1	μA	V _{OUT} =0V~V _{CC} , (SDA)
Current consumption at action	I _{CC1}	—	—	2.0 ^{*5}	mA	V _{CC} =5.5V, f _{SCL} =400kHz, t _{WR} =5ms, Byte write, Page write
	I _{CC2}	—	—	3.0 ^{*6}		V _{CC} =5.5V, f _{SCL} =400kHz Random read, current read, sequential read
Standby current	I _{SB}	—	—	2.0	μA	V _{CC} =5.5V, SDA · SCL=V _{CC} A0, A1, A2=GND, WP=GND

◎Radiation resistance design is not made.

^{*1} BR24L02/16/32-W : 1.7~5.5V, ^{*2} BR24L16/32-W, ^{*3} BR24L02/16-W, ^{*4} BR24L32-W

^{*5} BR24L01A/02/04/08/16-W, ^{*6} BR24L32/64-W

●Action timing characteristics (Unless otherwise specified, Ta=-40~+85°C, V_{CC}=1.8~5.5V) ^{*1}

Parameter	Symbol	FAST-MODE 2.5V≤V _{CC} ≤5.5V			STANDARD-MODE 1.8V≤V _{CC} ≤5.5V			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
SCL frequency	f _{SCL}	—	—	400	—	—	100	kHz
Data clock "HIGH" time	t _{HIGH}	0.6	—	—	4.0	—	—	μs
Data clock "LOW" time	t _{LOW}	1.2	—	—	4.7	—	—	μs
SDA, SCL rise time ^{*2}	t _R	—	—	0.3	—	—	1.0	μs
SDA, SCL fall time ^{*2}	t _F	—	—	0.3	—	—	0.3	μs
Start condition hold time	t _{HD:STA}	0.6	—	—	4.0	—	—	μs
Start condition setup time	t _{SU:STA}	0.6	—	—	4.7	—	—	μs
Input data hold time	t _{HD:DAT}	0	—	—	0	—	—	ns
Input data setup time	t _{SU:DAT}	100	—	—	250	—	—	ns
Output data delay time	t _{PD}	0.1	—	0.9	0.2	—	3.5	μs
Output data hold time	t _{DH}	0.1	—	—	0.2	—	—	μs
Stop condition setup time	t _{SU:STO}	0.6	—	—	4.7	—	—	μs
Bus release time before transfer start	t _{BUF}	1.2	—	—	4.7	—	—	μs
Internal write cycle time	t _{WR}	—	—	5	—	—	5	ms
Noise removal valid period (SDA, SCL terminal)	t _I	—	—	0.1	—	—	0.1	μs
WP hold time	t _{HD:WP}	0	—	—	0	—	—	ns
WP setup time	t _{SU:WP}	0.1	—	—	0.1	—	—	μs
WP valid time	t _{HIGH:WP}	1.0	—	—	1.0	—	—	μs

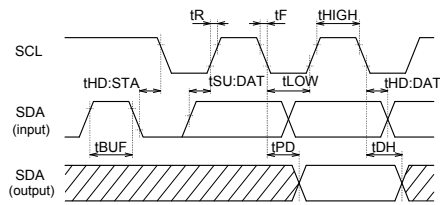
^{*1} BR24L02/16/32-W : 1.7~5.5V

^{*2} Not 100% tested

●FAST-MODE and STANDARD-MODE

FAST-MODE and STANDARD-MODE are of same actions, and mode is changed. They are distinguished by action speeds. 100kHz action is called STANDARD-MODE, and 400kHz action is called FAST-MODE. This action frequency is the maximum action frequency, so 100kHz clock may be used in FAST-MODE. When power source voltage goes down, action at high speed is not carried out, therefore, at V_{CC}=2.5V~5.5V, 400kHz, namely, action is made in FASTMODE. (Action is made also in STANDARD-MODE) V_{CC}=1.8V~2.5V is only action in 100kHz STANDARD-MODE.

●Sync data input / output timing



OInput read at the rise edge of SCL
OData output in sync with the fall of SCL

Fig.1-(a) Sync data input / output timing

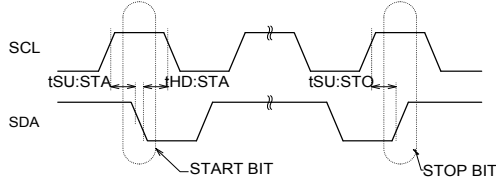


Fig.1-(b) Start-stop bit timing

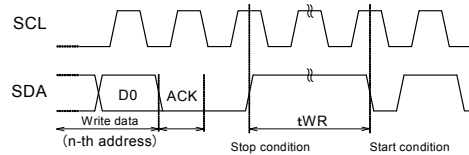


Fig.1-(c) Write cycle timing

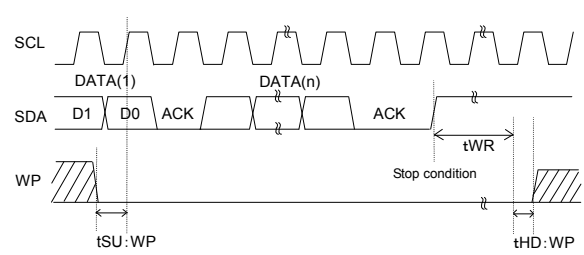
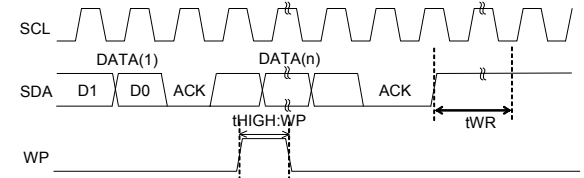


Fig.1-(d) WP timing at write execution



OAt write execution, in the area from the D0 taken clock rise of the first DATA(1), to tWR, set WP="LOW".

OBy setting WP "HIGH" in the area, write can be cancelled.

When it is set WP="HIGH" during tWR, write is forcibly ended, and data of address under access is not guaranteed, therefore write it once again.

Fig.1-(e) WP timing at write cancel

●Block diagram

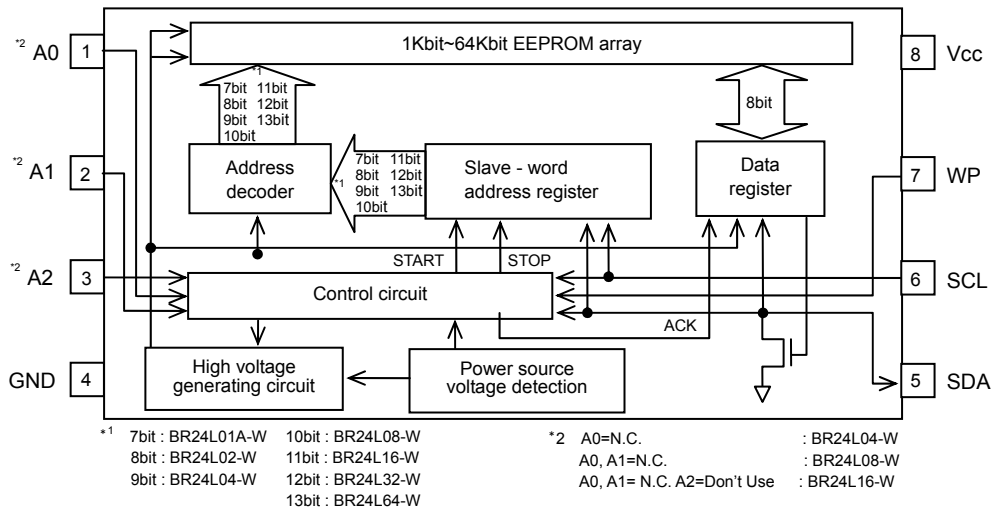
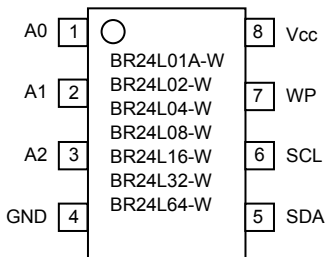


Fig.2 Block diagram

●Pin assignment and description



Terminal name	Input / output	Function						
		BR24L01A-W	BR24L02-W	BR24L04-W	BR24L08-W	BR24L16-W	BR24L32-W	BR24L64-W
A0	Input	Slave address setting		Not connected			Slave address setting	
A1	Input	Slave address setting			Not connected		Slave address setting	
A2	Input	Slave address setting				Not used	Slave address setting	
GND	-	Reference voltage of all input / output, 0V						
SDA	Input / output	Slave and word address, Serial data input serial data output						
SCL	Input	Serial clock input						
WP	Input	Write protect terminal						
Vcc	-	Connect the power source.						

●Characteristic data (The following values are Typ. ones.)

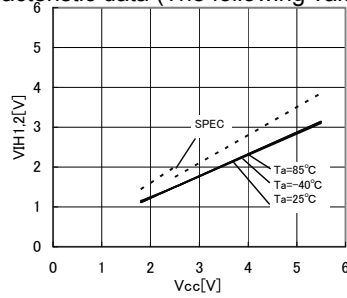


Fig.3 H input voltage $V_{IH1,2}$

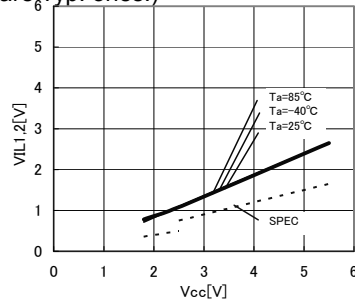


Fig.4 L input voltage $V_{IL1,2}$ (SCL,SDA,WP)

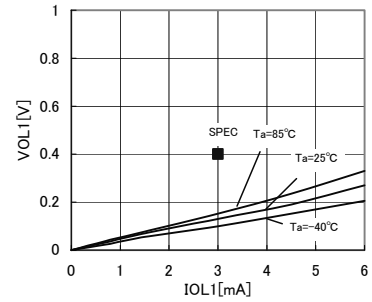


Fig.5 L output voltage $V_{OL1-IOL1}$ ($V_{CC} = 2.5\text{V}$)

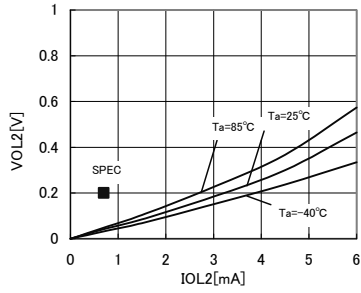


Fig.6 L output voltage $V_{OL2-IOL2}$ ($V_{CC} = 1.8\text{V}$)

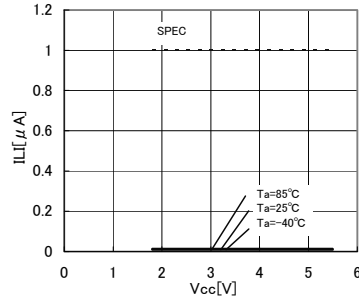


Fig.7 Input leak current I_{LI} (SCL,WP)

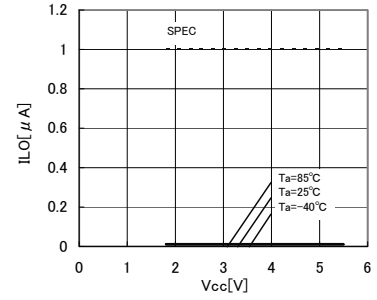


Fig.8 Output leak current $I_{LO}(\text{SDA})$

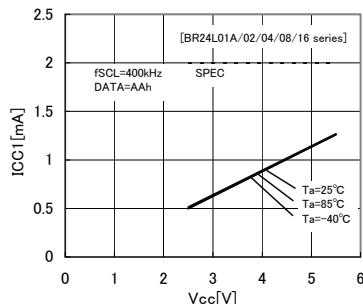


Fig.9 Current consumption at WRITE action I_{CC1} ($f_{SCL} = 400\text{kHz}$)

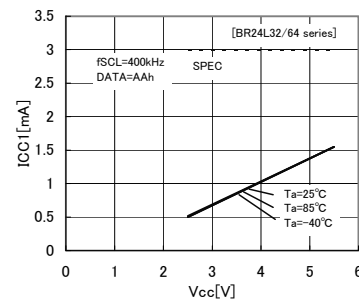


Fig.10 Current consumption at WRITE action I_{CC1} ($f_{SCL} = 400\text{kHz}$)

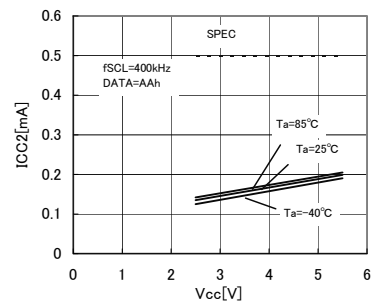


Fig.11 Current consumption at READ action I_{CC2} ($f_{SCL} = 400\text{kHz}$)

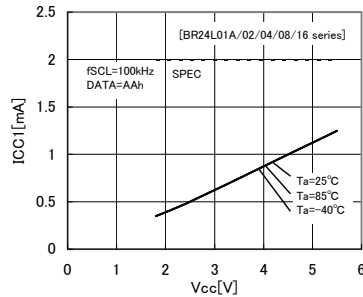


Fig.12 Current consumption at WRITE action I_{CC1} ($f_{SCL} = 100\text{kHz}$)

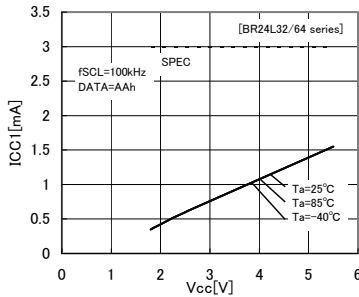


Fig.13 Current consumption at WRITE action I_{CC1} ($f_{SCL} = 100\text{kHz}$)

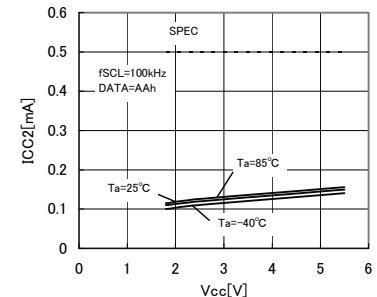


Fig.14 Current consumption at READ action I_{CC2} ($f_{SCL} = 100\text{kHz}$)

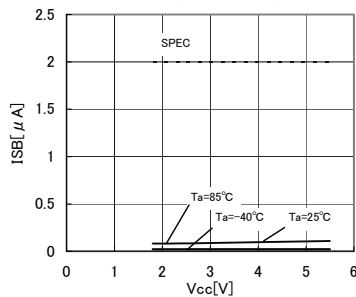


Fig.15 Standby current I_{SB}

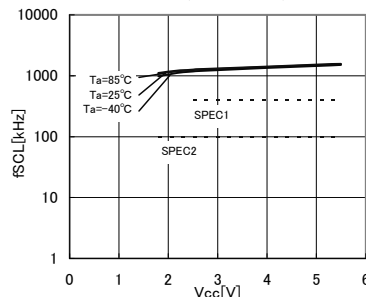


Fig.16 SCL frequency f_{SCL}

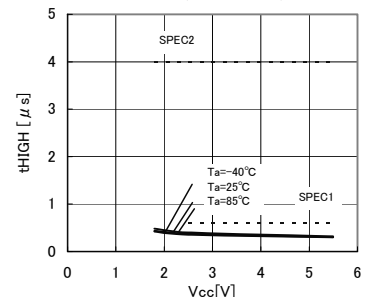


Fig.17 Data clock "H" time t_{HIGH}

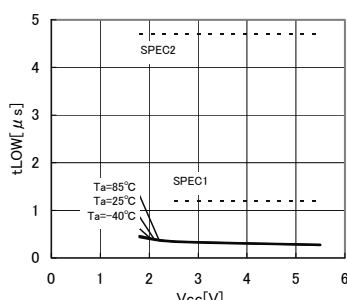


Fig.18 Data clock "L" time t_{LOW}

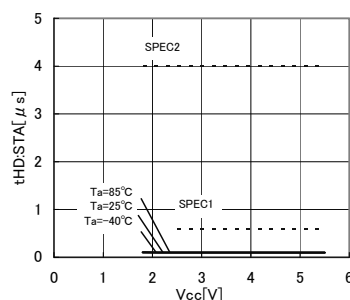


Fig.19 Start condition hold time $t_{HD:STA}$

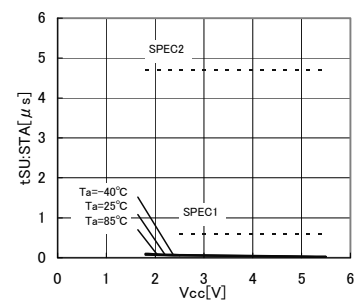


Fig.20 Start condition setup time $t_{SU:STA}$

●Characteristic data (The following values are Typ. ones).

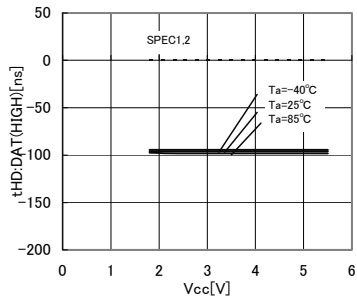


Fig.21 Input data hold time $t_{HD:DAT(HIGH)}$

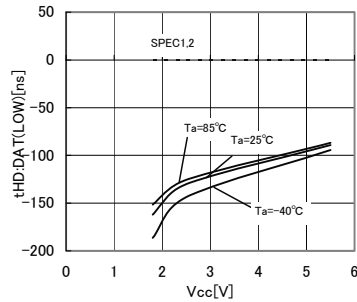


Fig.22 Input data hold time $t_{HD:DAT(LOW)}$

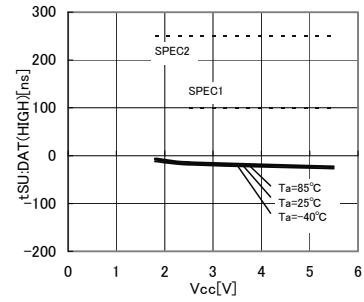


Fig.23 Input data setup time $t_{SU:DAT(HIGH)}$

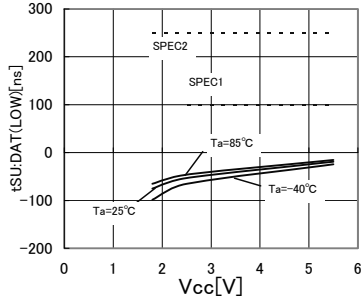


Fig.24 Input data setup time $t_{SU:DAT(LOW)}$

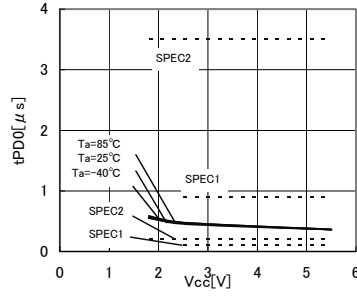


Fig.25 Output data delay time t_{PD0}

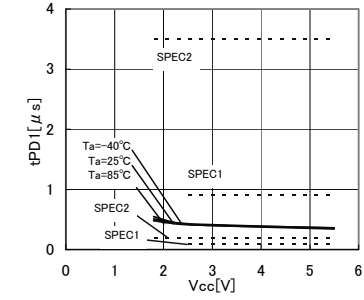


Fig.26 Output data delay time t_{PD1}

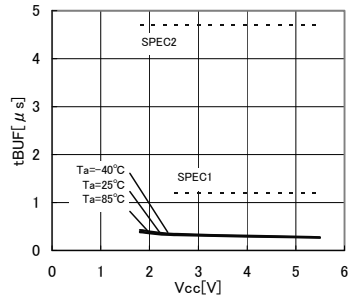


Fig.27 Bus release time before transfer start t_{BUF}

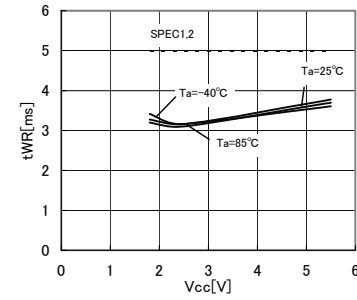


Fig.28 Internal write cycle time t_{WR}

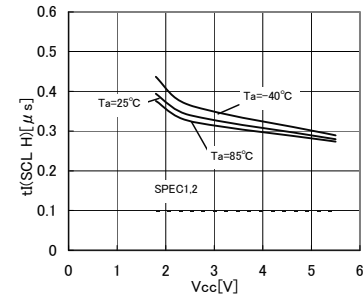


Fig.29 Noise removal valid time $t_{I(SCL H)}$

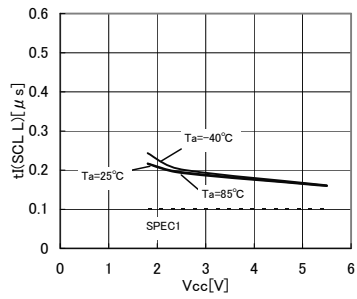


Fig.30 Noise removal valid time $t_{I(SCL L)}$

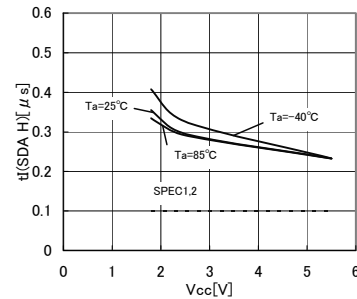


Fig.31 Noise removal valid time $t_{I(SDA H)}$

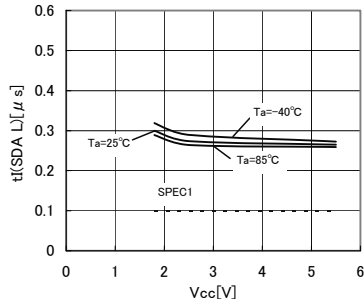


Fig.32 Noise removal valid time $t_{I(SDA L)}$

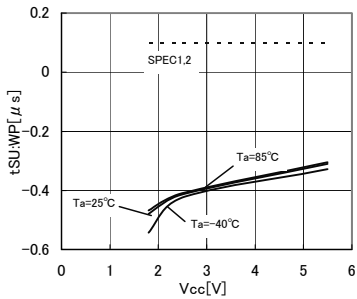


Fig.33 WP setup time $t_{SU:WP}$

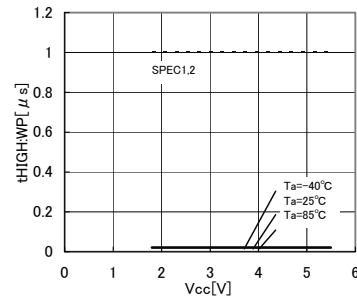


Fig.34 WP valid time $t_{HIGH:WP}$

● I²C BUS communication

○ I²C BUS data communication

I²C BUS data communication starts by start condition input, and ends by stop condition input. Data is always 8bit long, and acknowledge is always required after each byte. I²C BUS carries out data transmission with plural devices connected by 2 communication lines of serial data (SDA) and serial clock (SCL).

Among devices, there are “master” that generates clock and control communication start and end, and “slave” that is controlled by address peculiar to devices. EEPROM becomes “slave”. And the device that outputs data to bus during data communication is called “transmitter”, and the device that receives data is called “receiver”.

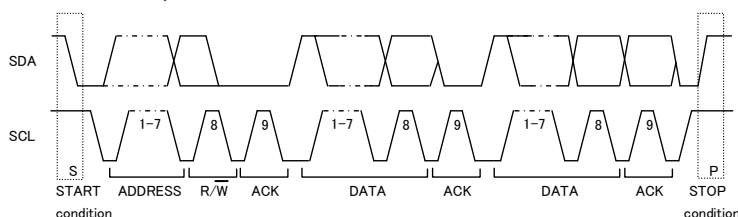


Fig.35 Data transfer timing

○ Start condition (Start bit recognition)

- Before executing each command, start condition (start bit) where SDA goes from 'HIGH' down to 'LOW' when SCL is 'HIGH' is necessary.
- This IC always detects whether SDA and SCL are in start condition (start bit) or not, therefore, unless this condition is satisfied, any command is executed.

○ Stop condition (stop bit recognition)

- Each command can be ended by SDA rising from 'LOW' to 'HIGH' when stop condition (stop bit), namely, SCL is 'HIGH'

○ Acknowledge (ACK) signal

- This acknowledge (ACK) signal is a software rule to show whether data transfer has been made normally or not. In master and slave, the device (μ -COM at slave address input of write command, read command, and this IC at data output of read command) at the transmitter (sending) side releases the bus after output of 8bit data.
- The device (this IC at slave address input of write command, read command, and μ -COM at data output of read command) at the receiver (receiving) side sets SDA 'LOW' during 9 clock cycles, and outputs acknowledge signal (ACK signal) showing that it has received the 8bit data.
- This IC, after recognizing start condition and slave address (8bit), outputs acknowledge signal (ACK signal) 'LOW'.
- Each write action outputs acknowledge signal (ACK signal) 'LOW', at receiving 8bit data (word address and write data).
- Each read action outputs 8bit data (read data), and detects acknowledge signal (ACK signal) 'LOW'.
- When acknowledge signal (ACK signal) is detected, and stop condition is not sent from the master (μ -COM) side, this IC continues data output. When acknowledge signal (ACK signal) is not detected, this IC stops data transfer, and recognizes stop condition (stop bit), and ends read action. And this IC gets in status.

○ Device addressing

- Output slave address after start condition from master.
- The significant 4 bits of slave address are used for recognizing a device type. The device code of this IC is fixed to '1010'.
- Next slave addresses (A2 A1 A0 --- device address) are for selecting devices, and plural ones can be used on a same bus according to the number of device addresses.
- The most insignificant bit (R/W --- READ / WRITE) of slave address is used for designating write or read action, and is as shown below.

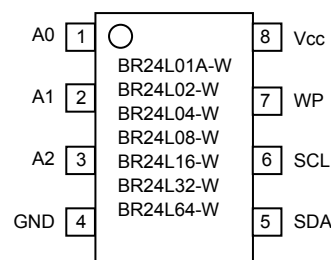
Setting $\overline{R/W}$ to 0 ----- write (setting 0 to word address setting of random read)

Setting $\overline{R/W}$ to 1 ----- read

Type	Slave address							Maximum number of connected buses
BR24L01A-W	1	0	1	0	A2	A1	A0 $\overline{R/W}$	8
BR24L02-W	1	0	1	0	A2	A1	A0 $\overline{R/W}$	8
BR24L04-W	1	0	1	0	A2	A1	PS $\overline{R/W}$	4
BR24L08-W	1	0	1	0	A2	P1	P0 $\overline{R/W}$	2
BR24L16-W	1	0	1	0	P2	P1	P0 $\overline{R/W}$	1
BR24L32-W	1	0	1	0	A2	A1	A0 $\overline{R/W}$	8
BR24L64-W	1	0	1	0	A2	A1	A0 $\overline{R/W}$	8

PS, P0~P2 are page select bits.

Note) Up to 4 units BR24L04-W, up to 2 units of BR24L08-W, and one unit of BR24L16-W can be connected.
Device address is set by 'H' and 'L' of each pin of A0, A1, and A2.



●Write Command

○Write cycle

- Arbitrary data is written to EEPROM. When to write only 1 byte, byte write is normally used, and when to write continuous data of 2 bytes or more, simultaneous write is possible by page write cycle. The maximum number of write bytes is specified per device of each capacity. Up to 32 arbitrary bytes can be written. (In the case of BR24L32 / L64-W)

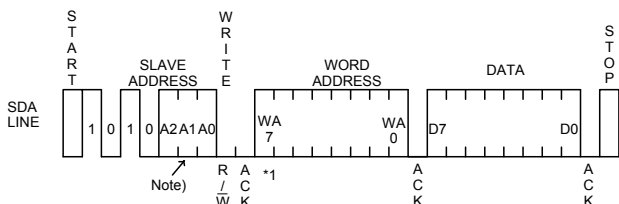


Fig.36 Byte write cycle (BR24L01A/02/04/08/16-W)

*1 As for WA7, BR24L01A-W becomes Don't care.

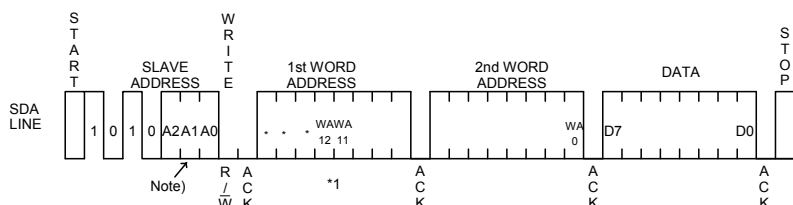


Fig.37 Byte write cycle (BR24L32/64-W)

*1 As for WA12, BR24L32-W becomes Don't care.

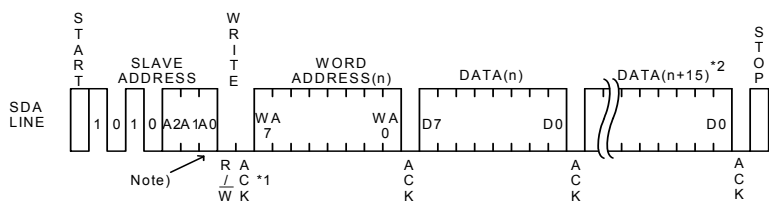


Fig.38 Page write cycle (BR24L01A/02/04/08/16-W)

*1 As for WA7, BR24L01A-W becomes Don't care.

*2 As for BR24L01A/02-W becomes (n+7).

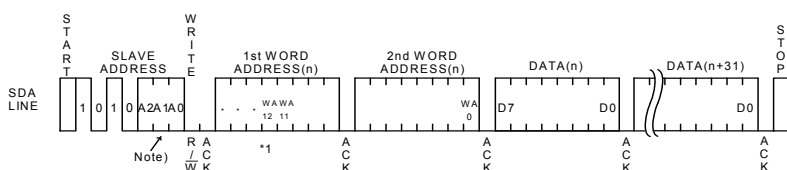


Fig.39 Page write cycle (BR24L32/64-W)

*1 As for WA12, BR24L32-W becomes Don't care.

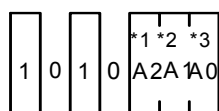
- Data is written to the address designated by word address (n-th address)
- By issuing stop bit after 8bit data input, write to memory cell inside starts.
- When internal write is started, command is not accepted for tWR (5ms at maximum).
- By page write cycle, the following can be written in bulk : Up to 8 bytes (BR24L01A-W, BR24L02-W)
: Up to 16bytes (BR24L04-W, BR24L08-W, BR24L16-W)
: Up to 32bytes (BR24L32-W, BR24L64-W)

And when data of the maximum bytes or higher is sent, data from the first byte is overwritten.

(Refer to "Internal address increment" of "Notes on page write cycle" in P9/32.)

- As for page write cycle of BR24L01A-W and BR24L02-W, after the significant 5 bits (4 significant bits in BR24L01-W) of word address are designated arbitrarily, and as for page write command of BR24L04-W, BR24L08-W, and BR24L16-W, after page select bit (PS) of slave address is designated arbitrarily, by continuing data input of 2 bytes or more, the address of insignificant 4 bits (insignificant 3 bit in BR24L01A-W, and BR24L02-W) is incremented internally, and data up to 16 bytes (up to 8 bytes in BR24L01A-W and BR24L02-W) can be written.
- As for page write cycle of BR24L32-W and BR24L64-W, after the significant 7 bits (in the case of BR24L32-W) of word address, or the significant 8 bits (in the case of BR24L64-W) of word address are designated arbitrarily, by continuing data input of 2 byte or more, the address of insignificant 5 bits is incremented internally, and data up to 32 bytes can be written.

Note)



*1 In BR24L16-W, A2 becomes P2.

*2 In BR24L08-W, BR24L16-W, A1 becomes P1.

*3 In BR24L04-W, A0 becomes PS, and in BR24L08-W and BR24L16-W, A0 becomes P0.

Fig.40 Difference of slave address of each type

Notes on write cycle continuous input

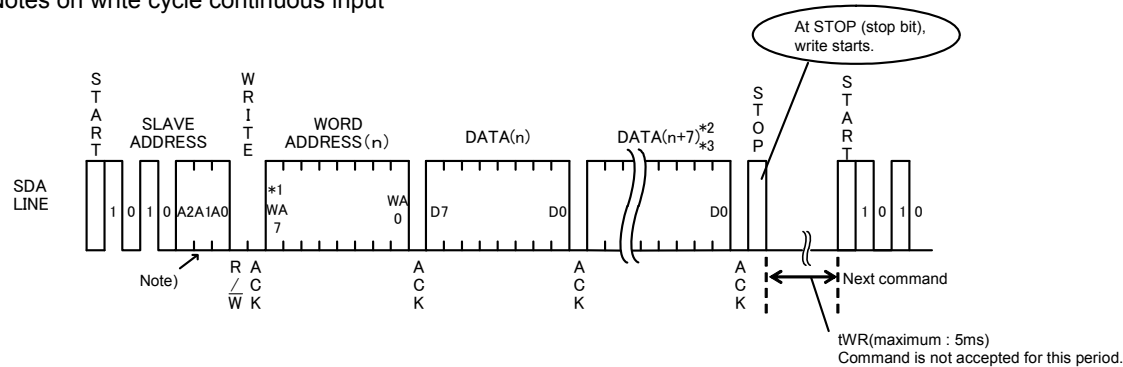


Fig.41 Page write cycle

- *1 BR24L01A-W becomes Don't care.
- *2 BR24L04-W, BR24L08-W, and BR24L16-W become (n+15).
- *3 BR24L32-W and BR24L64-W become (n+31).

Note)

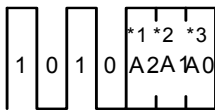


Fig.42 Difference of each type of slave address

- *1 In BR24L16-W, A2 becomes P2.
- *2 In BR24L08-W, BR24L16-W, A1 becomes P1.
- *3 In BR24L04-W, A0 becomes PS, and in BR24L08-W and in BR24L16-W, A0 becomes P0.

Notes on page write cycle

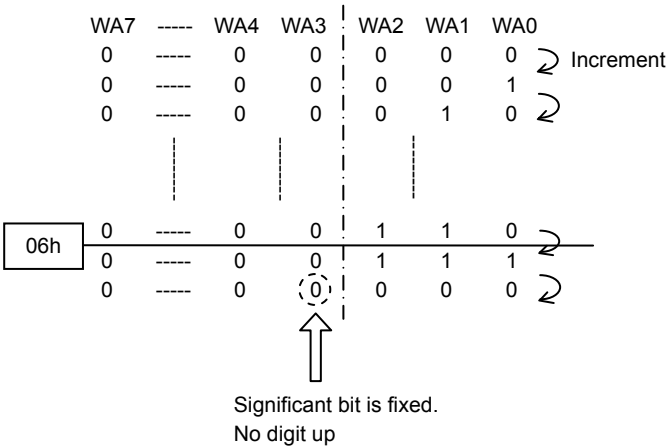
List of numbers of page write

Number of Pages	8Byte	16Byte	32Byte
Product number	BR24L01A-W BR24L02-W	BR24L04-W BR24L08-W BR24L16-W	BR24L32-W BR24L64-W

The above numbers are maximum bytes for respective types.
Any bytes below these can be written.

In the case BR24L02-W, 1 page=8bytes, but the page write cycle write time is 5ms at maximum for 8byte bulk write.
It does not stand 5ms at maximum × 8byte=40ms(Max.).

Internal address increment
Page write mode (in the case of BR24L02-W)



For example, when it is started from address 06h, therefore, increment is made as below,
06h → 07h → 00h → 01h ---, which please note.
* 06h...06 in hexadecimal, therefore, 00000110 becomes a binary number.

Write protect (WP) terminal

- Write protect (WP) function

When WP terminal is set Vcc (H level), data rewrite of all addresses is prohibited. When it is set GND (L level), data rewrite of all address is enabled. Be sure to connect this terminal to Vcc or GND, or control it to H level or L level. Do not use it open.

At extremely low voltage at power ON / OFF, by setting the WP terminal 'H', mistake write can be prevented.

During tWR, set the WP terminal always to 'L'. If it is set 'H', write is forcibly terminated.

●Read Command

○Read cycle

Data of EEPROM is read. In read cycle, there are random read cycle and current read cycle.

Random read cycle is a command to read data by designating address, and is used generally.

Current read cycle is a command to read data of internal address register without designating address, and is used when to verify just after write cycle. In both the read cycles, sequential read cycle is available, and the next address data can be read in succession.

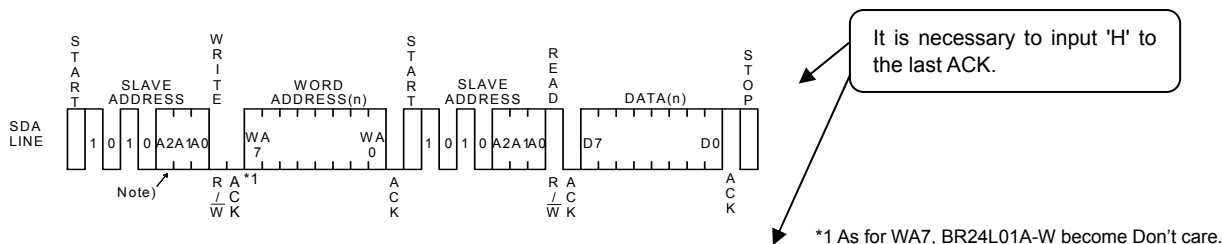


Fig.43 Random read cycle (BR24L01A/02/04/08/16-W)

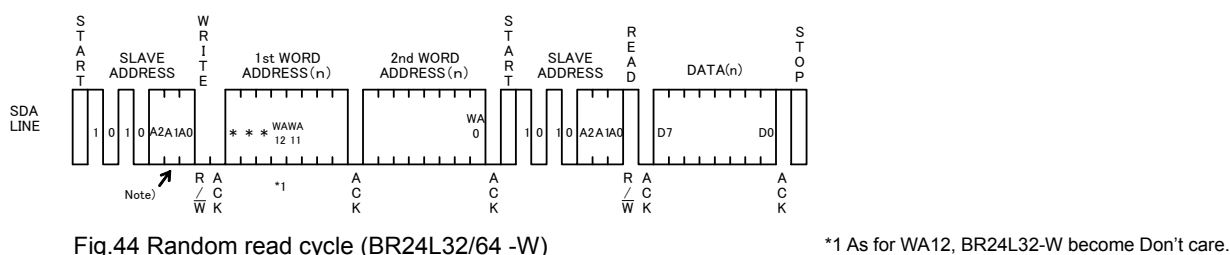


Fig.44 Random read cycle (BR24L32/64 -W)

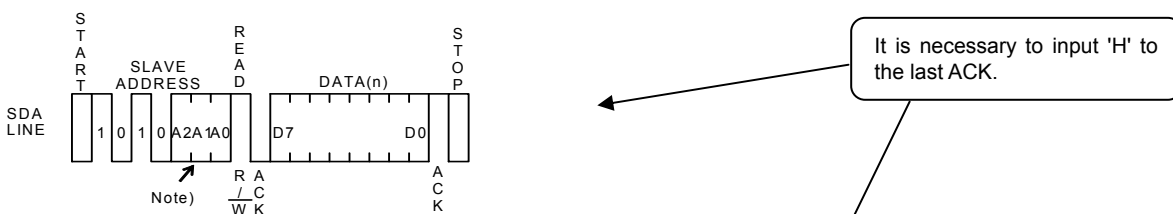


Fig.45 Current read cycle

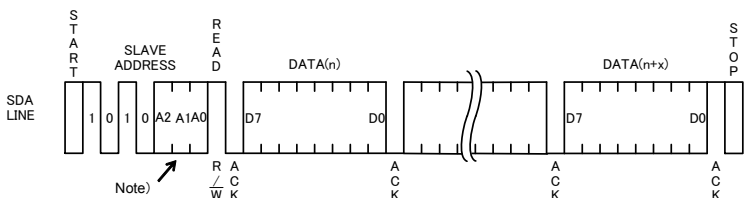
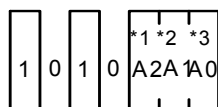


Fig.46 Sequential read cycle (in the case of current read cycle)

- In random read cycle, data of designated word address can be read.
 - When the command just before current read cycle is random read cycle, current read cycle (each including sequential read cycle), data of incremented last read address (n)-th address, i.e., data of the (n+1)-th address is output.
 - When ACK signal 'LOW' after D0 is detected, and stop condition is not sent from master (μ -COM) side, the next address data can be read in succession.
 - Read cycle is ended by stop condition where 'H' is input to ACK signal after D0 and SDA signal is started at SCL signal 'H'.
 - When 'H' is not input to ACK signal after D0, sequential read gets in, and the next data is output.
- Therefore, read command cycle cannot be ended. When to end read command cycle, be sure input stop condition to input 'H' to ACK signal after D0, and to start SDA at SCL signal 'H'.
- Sequential read is ended by stop condition where 'H' is input to ACK signal after arbitrary D0 and SDA is started at SCL signal 'H'.

Note)



*1 In BR24L16-W, A2 becomes P2.

*2 In BR24L08-W, BR24L16-W, A1 becomes P1.

*3 In BR24L04-W, A0 becomes PS, and in BR24L08-W and BR24L16-W, A0 becomes P0.

Fig.47 Difference of slave address of each type

● Software reset

Software reset is executed when to avoid malfunction after power on, and to reset during command input. Software reset has several kinds, and 3 kinds of them are shown in the figure below. (Refer to Fig.48(a), Fig.48(b), and Fig.48(c).) In dummy clock input area, release the SDA bus ('H' by pull up). In dummy clock area, ACK output and read data '0' (both 'L' level) may be output from EEPROM, therefore, if 'H' is input forcibly, output may conflict and over current may flow, leading to instantaneous power failure of system power source or influence upon devices.

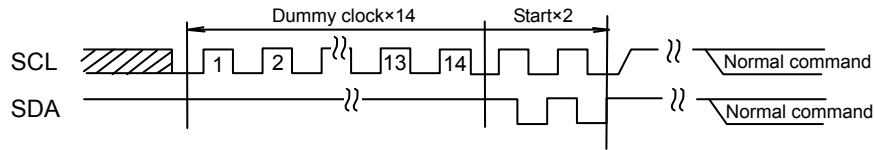


Fig.48-(a) The case of dummy clock +START+START+ command input

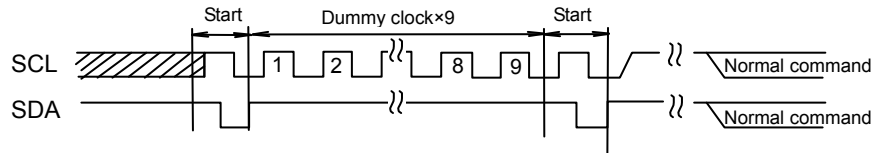


Fig.48-(b) The case of START +9 dummy clocks +START+ command input

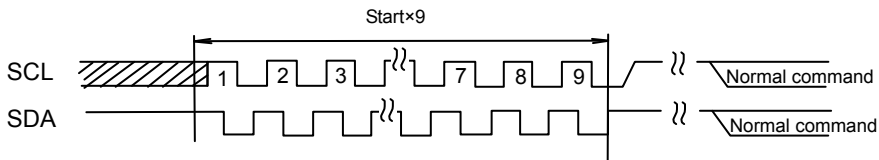


Fig.48-(c) START x 9+ command input

※ Start command from START input.

● Acknowledge polling

During internal write execution, all input commands are ignored, therefore ACK is not sent back. During internal automatic write execution after write cycle input, next command (slave address) is sent, and if the first ACK signal sends back 'L', then it means end of write action, while if it sends back 'H', it means now in writing. By use of acknowledge polling, next command can be executed without waiting for $t_{WR} = 5\text{ms}$.

When to write continuously, $R/\overline{W} = 0$, when to carry out current read cycle after write, slave address $R/\overline{W} = 1$ is sent, and if ACK signal sends back 'L', then execute word address input and data output and so forth.

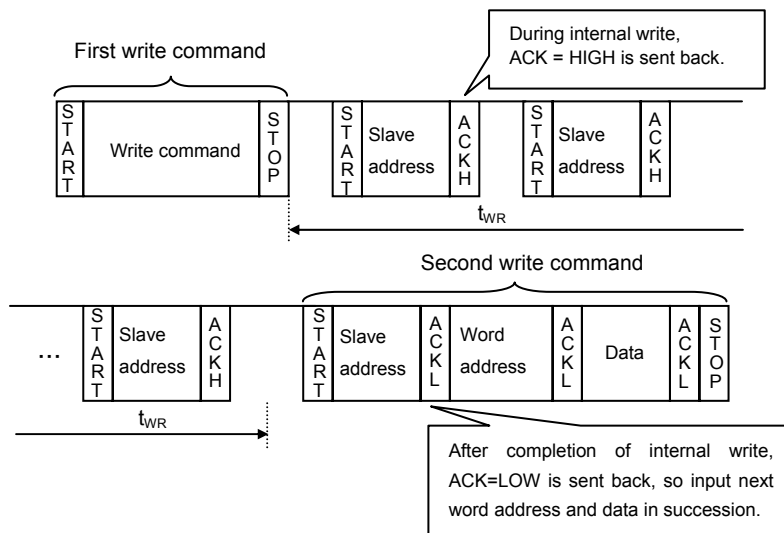


Fig.49 Case to continuously write by acknowledge polling

●WP valid timing (write cancel)

WP is usually fixed to 'H' or 'L', but when WP is used to cancel write cycle and so forth, pay attention to the following WP valid timing. During write cycle execution, in cancel valid area, by setting WP='H', write cycle can be cancelled. In both byte write cycle and page write cycle, the area from the first start condition of command to the rise of clock to taken in D0 of data (in page write cycle, the first byte data) is cancel invalid area.

WP input in this area becomes Don't care. Set the setup time to rise of D0 taken SCL 100ns or more. The area from the rise of SCL to take in D0 to the end of internal automatic write (tWR) is cancel valid area. And, when it is set WP='H' during tWR, write is ended forcibly, data of address under access is not guaranteed, therefore, write it once again. (Refer to Fig.50.) After execution of forced end by WP, standby status gets in, so there is no need to wait for tWR (5ms at maximum).

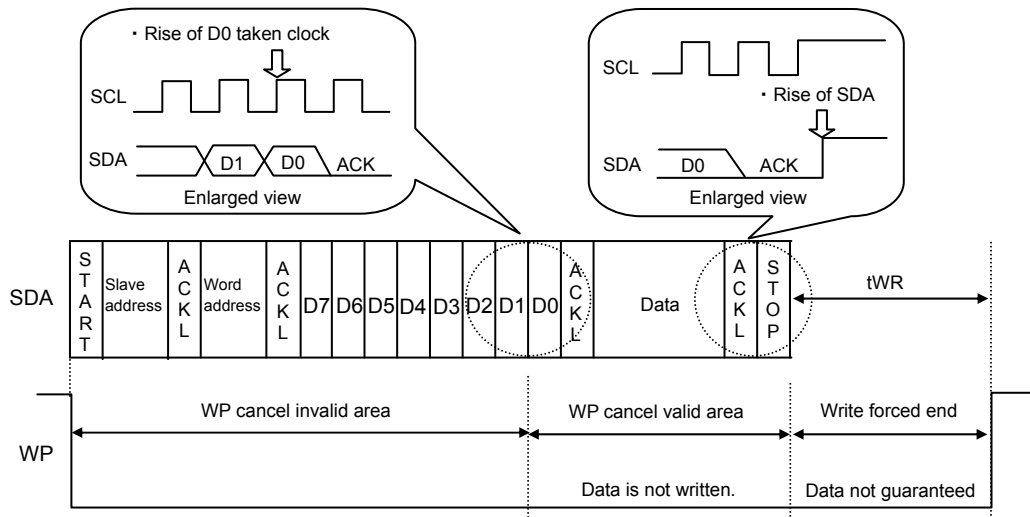


Fig.50 WP valid timing

●Command cancel by start condition and stop condition

During command input, by continuously inputting start condition and stop condition, command can be cancelled.

(Refer to Fig. 51.)

However, in ACK output area and during data read, SDA bus may output 'L', and in this case, start condition and stop condition cannot be input, so reset is not available. Therefore, execute software reset. And when command is cancelled by start, stop condition, during random read cycle, sequential read cycle, or current read cycle, internal setting address is not determined, therefore, it is not possible to carry out current read cycle in succession. When to carry out read cycle in succession, carry out random read cycle.

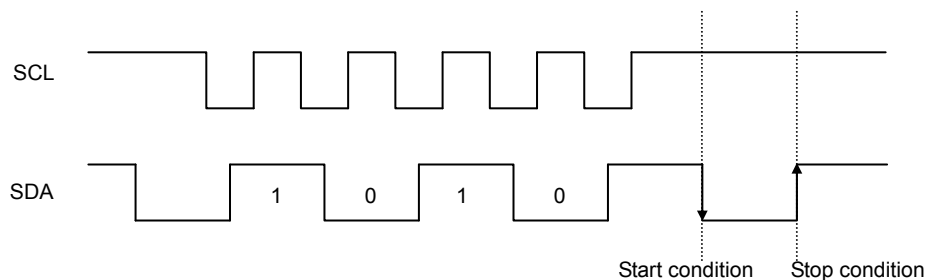


Fig.51 Case of cancel by start, stop condition during slave address input

● I/O peripheral circuit

○ Pull up resistance of SDA terminal

SDA is NMOS open drain, so requires pull up resistance. As for this resistance value (R_{PU}), select an appropriate value to this resistance value from microcontroller V_{IL} , I_L , and $V_{OL}-I_{OL}$ characteristics of this IC. If R_{PU} is large, action frequency is limited. The smaller the R_{PU} , the larger the consumption current at action.

○ Maximum value of R_{PU}

The maximum value of R_{PU} is determined by the following factors.

(1) SDA rise time to be determined by the capacitance (CBUS) of bus line of R_{PU} and SDA should be t_R or below.

And AC timing should be satisfied even when SDA rise time is late.

(2) The bus electric potential (A) to be determined by input leak total (I_L) of device connected to bus at output of 'H' to SDA bus and R_{PU} should sufficiently secure the input 'H' level (V_{IH}) of microcontroller and EEPROM including recommended noise margin 0.2Vcc.

$$V_{CC} - I_L R_{PU} - 0.2V_{CC} \geq V_{IH}$$

$$\therefore R_{PU} = \frac{0.8V_{CC} - V_{IH}}{I_L}$$

Ex.) When $V_{CC}=3V$, $I_L=10\mu A$, $V_{IH}=0.7V_{CC}$,
from (2)

$$R_{PU} \leq \frac{0.8 \times 3 - 0.7 \times 3}{10 \times 10^{-6}} \\ \leq 300 [k\Omega]$$

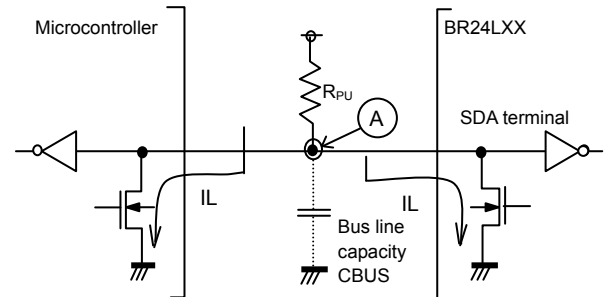


Fig.52 I/O circuit diagram

○ Minimum value of R_{PU}

The minimum value of R_{PU} is determined by the following factors.

(1) When IC outputs LOW, it should be satisfied that $V_{OLMAX}=0.4V$ and $I_{OLMAX}=3mA$.

$$\frac{V_{CC} - V_{OL}}{R_{PU}} \leq I_{OL} \quad \therefore R_{PU} \leq \frac{V_{CC} - V_{OL}}{I_{OL}}$$

(2) $V_{OLMAX}=0.4V$ should secure the input 'L' level (V_{IL}) of microcontroller and EEPROM including recommended noise margin 0.1Vcc.

$$V_{OLMAX} \leq V_{IL} - 0.1V_{CC}$$

Ex.) When $V_{CC}=3V$, $V_{OL}=0.4V$, $I_{OL}=3mA$, microcontroller, EEPROM $V_{IL}=0.3V_{CC}$

from (1)

$$R_{PU} \geq \frac{3 - 0.4}{3 \times 10^{-3}} \\ \geq 867 [\Omega]$$

And

$$V_{OL} = 0.4 [V]$$

$$V_{IL} = 0.3 \times 3$$

$$= 0.9 [V]$$

Therefore, the condition (2) is satisfied.

○ Pull up resistance of SCL terminal

When SCL control is made at CMOS output port, there is no need, but in the case there is timing where SCL becomes 'Hi-Z', add a pull up resistance. As for the pull up resistance, one of several $k\Omega$ ~ several ten $k\Omega$ is recommended in consideration of drive performance of output port of microcontroller.

● A0, A1, A2, WP process

○ Process of device address terminals (A0,A1,A2)

Check whether the set device address coincides with device address input sent from the master side or not, and select one among plural devices connected to a same bus. Connect this terminal to pull up or pull down, or Vcc or GND. And, pins (N, C, PIN) not used as device address may be set to any of 'H', 'L', and 'Hi-Z'.

Types with N.C.PIN	BR24L16/F/FJ/FV/FVT/FVM/FVJ-W	A0, A1, A2
	BR24L08/F/FJ/FV/FVT/FVM/FVJ/NUX-W	A0, A1
	BR24L04/F/FJ/FV/FVT/FVM/FVJ/NUX-W	A0

○ Process of WP terminal

WP terminal is the terminal that prohibits and permits write in hardware manner. In 'H' status, only READ is available and WRITE of all address is prohibited. In the case of 'L', both are available. In the case of use it as an ROM, it is recommended to connect it to pull up or Vcc. In the case to use both READ and WRITE, control WP terminal or connect it to pull down or GND.

●Cautions on microcontroller connection

ORs

In I²C BUS, it is recommended that SDA port is of open drain input/output. However, when to use CMOS input / output of tri state to SDA port, insert a series resistance R_s between the pull up resistance R_{pu} and the SDA terminal of EEPROM. This controls over current that occurs when PMOS of the microcontroller and NMOS of EEPROM are turned ON simultaneously. R_s also plays the role of protection of SDA terminal against surge. Therefore, even when SDA port is open drain input/output, R_s can be used.

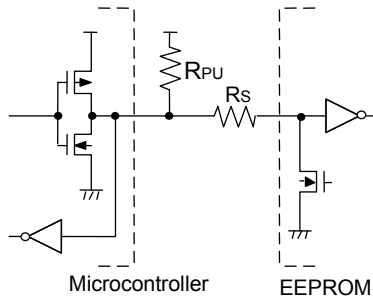


Fig.53 I/O circuit diagram

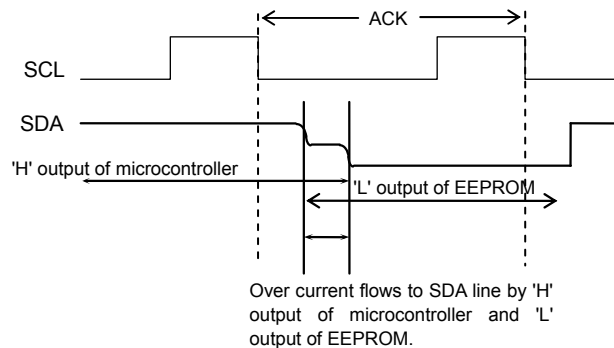


Fig.54 Input / output collision timing

OMaximum value of R_s

The maximum value of R_s is determined by the following relations.

- (1) SDA rise time to be determined by the capacity (C_{BUS}) of bus line of R_{pu} and SDA should be t_R or below. And AC timing should be satisfied even when SDA rise time is late.
- (2) The bus electric potential Φ to be determined by R_{pu} and R_s the moment when EEPROM outputs 'L' to SDA bus should sufficiently secure the input 'L' level (V_{IL}) of microcontroller including recommended noise margin 0.1V_{CC}.

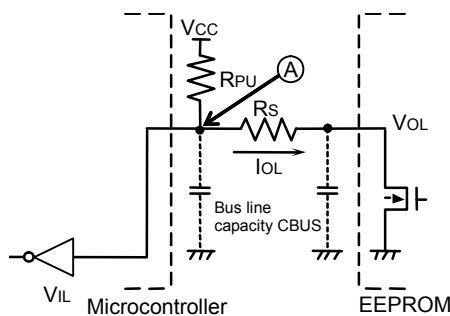


Fig.55 I/O circuit diagram

$$\frac{(V_{CC}-V_{OL}) \times R_S}{R_{PU}+R_S} + V_{OL} + 0.1V_{CC} \leq V_{IL}$$

$$\therefore R_S \leq \frac{V_{IL}-V_{OL}-0.1V_{CC}}{1.1V_{CC}-V_{IL}} \times R_{PU}$$

Example) When V_{CC}=3V, V_{IL}=0.3V_{CC}, V_{OL}=0.4V, R_{PU}=20k Ω ,

$$\text{from (2), } R_S \leq \frac{0.3 \times 3 - 0.4 - 0.1 \times 3}{1.1 \times 3 - 0.3 \times 3} \times 20 \times 10^3$$

$$\leq 1.67[\text{k}\Omega]$$

OMinimum value of R_s

The minimum value of R_s is determined by over current at bus collision. When over current flows, noises in power source line, and instantaneous power failure of power source may occur. When allowable over current is defined as I, the following relation must be satisfied. Determine the allowable current in consideration of impedance of power source line in set and so forth. Set the over current to EEPROM 10mA or below.

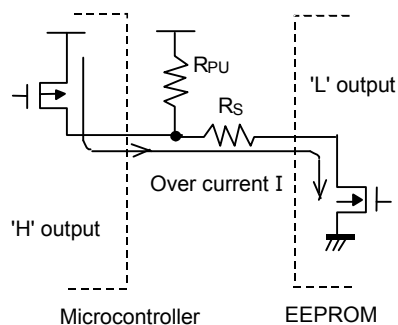


Fig.56 I/O circuit diagram

$$\frac{V_{CC}}{R_S} \leq I$$

$$\therefore R_S \geq \frac{V_{CC}}{I}$$

Example) When V_{CC}=3V, I=10mA

$$R_S \geq \frac{3}{10 \times 10^{-3}}$$

$$\geq 300[\Omega]$$

- I²C BUS input / output circuit
- Input (A0,A2,SCL)

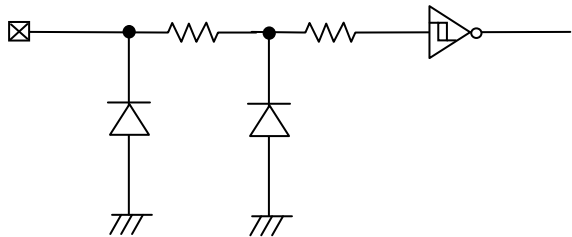


Fig.57 Input pin circuit diagram

- Input / output (SDA)

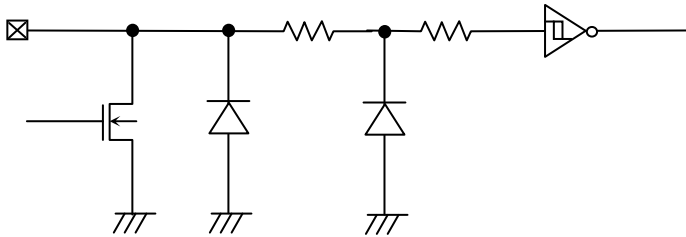


Fig.58 Input / output pin circuit diagram

- Input (A1, WP)

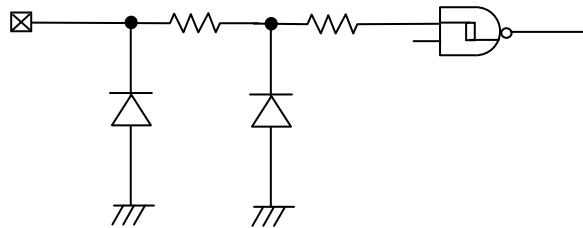


Fig.59 Input pin circuit diagram

- Notes on power ON
- At power on, in IC internal circuit and set, Vcc rises through unstable low voltage area, and IC inside is not completely reset, and malfunction may occur. To prevent this, functions of POR circuit and LVCC circuit are equipped. To assure the action, observe the following conditions at power on.
1. Set SDA = 'H' and SCL ='L' or 'H'
 2. Start power source so as to satisfy the recommended conditions of t_R, t_{OFF}, and Vbot for operating POR circuit.

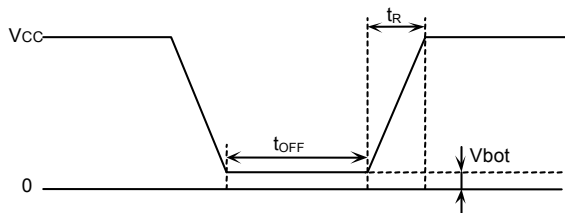


Fig.60 Rise waveform diagram

Recommended conditions of t _R , t _{OFF} , Vbot		
t _R	t _{OFF}	Vbot
10ms or below	10ms or longer	0.3V or below
100ms or below	10ms or longer	0.2V or below

3. Set SDA and SCL so as not to become 'Hi-Z'.

When the above conditions 1 and 2 cannot be observed, take the following countermeasures.

- a) In the case when the above condition 1 cannot be observed. When SDA becomes 'L' at power on .
 →Control SCL and SDA as shown below, to make SCL and SDA, 'H' and 'H'.

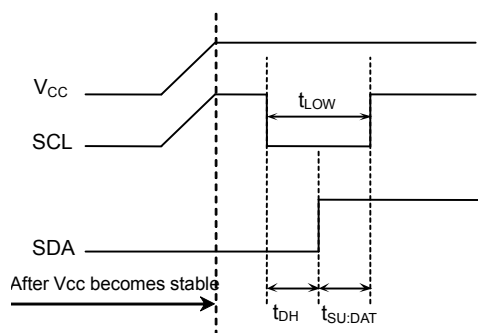


Fig.61 When SCL= 'H' and SDA= 'L'

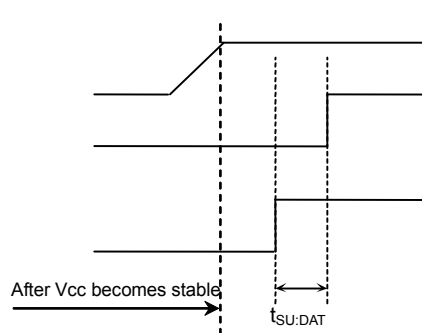


Fig.62 When SCL='L' and SDA='L'

- b) In the case when the above condition 2 cannot be observed.
 →After power source becomes stable, execute software reset(P11).
- c) In the case when the above conditions 1 and 2 cannot be observed.
 →Carry out a), and then carry out b).

●Low voltage malfunction prevention function

LVCC circuit prevents data rewrite action at low power, and prevents wrong write. At LVCC voltage (Typ. =1.2V) or below, it prevent data rewrite.

●Vcc noise countermeasures

○Bypass capacitor

When noise or surge gets in the power source line, malfunction may occur, therefore, for removing these, it is recommended to attach a by pass capacitor (0.1μF) between IC Vcc and GND. At that moment, attach it as close to IC as possible.

And, it is also recommended to attach a bypass capacitor between board Vcc and GND.

●Cautions on use

- (1)Described numeric values and data are design representative values, and the values are not guaranteed.
- (2)We believe that application circuit examples are recommendable, however, in actual use, confirm characteristics further sufficiently. In the case of use by changing the fixed number of external parts, make your decision with sufficient margin in consideration of static characteristics and transition characteristics and fluctuations of external parts and our LSI.
- (3)Absolute maximum ratings
 If the absolute maximum ratings such as impressed voltage and action temperature range and so forth are exceeded, LSI may be destructed. Do not impress voltage and temperature exceeding the absolute maximum ratings. In the case of fear exceeding the absolute maximum ratings, take physical safety countermeasures such as fuses, and see to it that conditions exceeding the absolute maximum ratings should not be impressed to LSI.
- (4)GND electric potential
 Set the voltage of GND terminal lowest at any action condition. Make sure that each terminal voltage is lower than that of GND terminal.
- (5)Terminal design
 In consideration of permissible loss in actual use condition, carry out heat design with sufficient margin.
- (6)Terminal to terminal shortcircuit and wrong packaging
 When to package LSI onto a board, pay sufficient attention to LSI direction and displacement. Wrong packaging may destruct LSI. And in the case of shortcircuit between LSI terminals and terminals and power source, terminal and GND owing to foreign matter, LSI may be destructed.
- (7)Use in a strong electromagnetic field may cause malfunction, therefore, evaluate design sufficiently.

I²C BUS Serial EEPROMs

BR24S□□□-W Series

BR24S16-W, BR24S32-W, BR24S64-W, BR24S128-W, BR24S256-W

●Description

BR24S□□□-W series is a serial EEPROM of I²C BUS interface method.

●Features

- Completely conforming to the world standard I²C BUS. All controls available by 2 ports of serial clock (SCL) and serial data (SDA)
- Other devices than EEPROM can be connected to the same port, saving microcontroller port.
- 1.7~5.5V single power source action most suitable for battery use.
- FAST MODE 400kHz at 1.7~5.5V
- Page write mode useful for initial value write at factory shipment.
- Highly reliable connection by Au pad and Au wire.
- Auto erase and auto end function at data rewrite.
- Low current consumption
 - At write operation (5V) : 0.5mA (Typ.)
 - At read operation (5V) : 0.2mA (Typ.)
 - At standby operation (5V) : 0.1 μ A (Typ.)
- Write mistake prevention function
 - Write (write protect) function added
 - Write mistake prevention function at low voltage
- SOP8/SOP-J8/SSOP-B8/TSSOP-B8/MSOP8/TSSOP-B8J/VSON008X2030 compact package
- Data rewrite up to 1,000,000 times
- Data kept for 40 years
- Noise filter built in SCL / SDA terminal
- Shipment data all address FFh

Page write

Number of pages	16Byte	32Byte	64Byte
Product number	BR24S16-W	BR24S32-W BR24S64-W	BR24S128-W BR24S256-W

●BR24S series

Capacity	Bit format	Type	Power source voltage	SOP8	SOP-J8	SSOP-B8	TSSOP-B8	MSOP8	TSSOP-B8J	VSON008 X2030
				F	FJ	FV	FVT	FVM	FVJ	NUX
16Kbit	2K×8	BR24S16-W	1.7~5.5V	●	●	●	●	●	●	●
32Kbit	4K×8	BR24S32-W	1.7~5.5V	●	●	●	●	●	●	●
64Kbit	8K×8	BR24S64-W	1.7~5.5V	●	●	●	●	●	●	
128Kbit	16K×8	BR24S128-W	1.7~5.5V	●	●	●	●			
256Kbit	32K×8	BR24S256-W	1.7~5.5V	●	●					

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Impressed voltage	V _{CC}	-0.3~+6.5	V
Permissible dissipation	Pd	450(SOP8) *1	mW
		450(SOP-J8) *2	
		300(SSOP-B8) *3	
		330(TSSOP-B8) *4	
		310(MSOP8) *5	
		310(TSSOP-B8J) *6	
		300(VSON008X2030) *7	
Storage temperature range	T _{stg}	-65 ~ +125	°C
Action temperature range	T _{opr}	-40 ~ +85	°C
Terminal Voltage	—	-0.3~V _{CC} +1.0	V

* When using at Ta=25°C or higher, 4.5mW(*1,*2) 3.0mW(*3,*7) 3.3mW(*4) 3.1mW(*5,*6) to be reduced per 1°C

●Memory cell characteristics (Ta=25°C, V_{CC}=1.7V~5.5V)

Parameter	Limits			Unit
	Min.	Typ.	Max.	
Number of data rewrite times *1	1,000,000	—	—	Times
Data hold years *1	40	—	—	Years

*1 : Not 100% TESTED

●Recommended operating condition

Parameter	Symbol	Limits	Unit
Power source voltage	V _{CC}	1.7~5.5	V
Input voltage	V _{IN}	0~V _{CC}	

●Electrical characteristics

(Unless otherwise specified, Ta=-40~+85°C, V_{CC}=1.7~5.5V)

Parameter	Symbol	Limits			Unit	Condition
		Min.	Typ.	Max.		
"H" Input Voltage1	V _{IH1}	0.7V _{CC}	—	V _{CC} +1.0	V	
"L" Input Voltage1	V _{IL1}	-0.3	—	0.3V _{CC}	V	
"L" Output Voltage1	V _{OL1}	—	—	0.4	V	I _{OL} =3.0mA, 2.5V≤V _{CC} ≤5.5V (SDA)
"L" Output Voltage2	V _{OL2}	—	—	0.2	V	I _{OL} =0.7mA, 1.7V≤V _{CC} ≤2.5V (SDA)
Input Leakage Current	I _{LI}	-1	—	1	μA	V _{IN} =0~V _{CC}
Output Leakage Current	I _{LO}	-1	—	1	μA	V _{OUT} =0~V _{CC} (SDA)
Current consumption at action	I _{CC1}	—	—	2.0	mA	V _{CC} =5.5V, f _{SCL} =400kHz, t _{WR} =5ms Byte Write, Page Write BR24S16/32/64-W
		—	—	2.5		V _{CC} =5.5V, f _{SCL} =400kHz, t _{WR} =5ms Byte Write, Page Write BR24S128/256-W
	I _{CC2}	—	—	0.5	mA	V _{CC} =5.5V, f _{SCL} =400kHz Random read, Current read, Sequential read
Standby Current	I _{SB}	—	—	2.0	μA	V _{CC} =5.5V, SDA = SCL = V _{CC} A0, A1, A2=GND, WP=GND

ORadiation resistance design is not made.

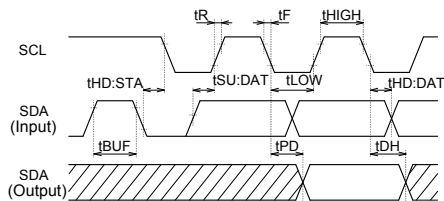
●Action timing characteristics

(Unless otherwise specified, Ta=-40~+85°C, V_{CC}=1.7~5.5V)

Parameter	Symbol	Limits			Unit
		Min.	Typ.	Max.	
SCL Frequency	f _{SCL}	—	—	400	kHz
Data clock "High" time	t _{HIGH}	0.6	—	—	μs
Data clock "Low" time	t _{LOW}	1.2	—	—	μs
SDA, SCL rise time *1	t _R	—	—	0.3	μs
SDA, SCL fall time *1	t _F	—	—	0.3	μs
Start condition hold time	t _{HD:STA}	0.6	—	—	μs
Start condition setup time	t _{SU:STA}	0.6	—	—	μs
Input data hold time	t _{HD:DAT}	0	—	—	ns
Input data setup time	t _{SU:DAT}	100	—	—	ns
Output data delay time	t _{PD}	0.1	—	0.9	μs
Output data hold time	t _{DH}	0.1	—	—	μs
Stop condition data setup time	t _{SU:STO}	0.6	—	—	μs
Bus release time before transfer start	t _{BUF}	1.2	—	—	μs
Internal write cycle time	t _{WR}	—	—	5	ms
Noise removal valid period (SDA,SCL terminal)	t _I	—	—	0.1	μs
WP hold time	t _{HD:WP}	0	—	—	ns
WP setup time	t _{SU:WP}	0.1	—	—	μs
WP valid time	t _{HIGH:WP}	1.0	—	—	μs

*1 : Not 100% TESTED

●Sync data input/output timing



OInput read at the rise edge of SCL
OData output in sync with the fall of SCL

Fig.1-(a) Sync data input / output timing

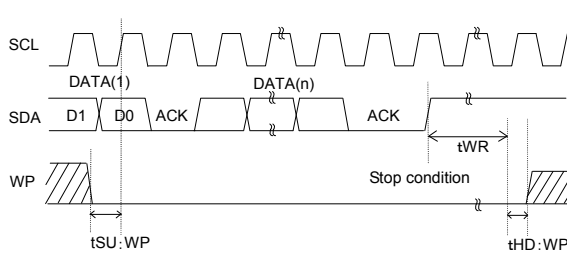


Fig.1-(d) WP timing at write execution

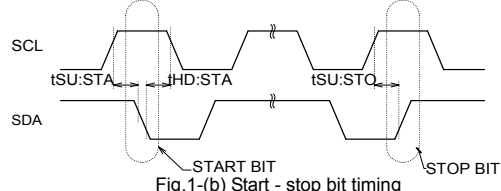


Fig.1-(b) Start - stop bit timing

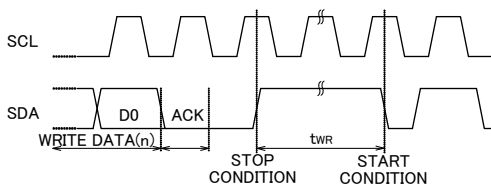


Fig.1-(c) Write cycle timing

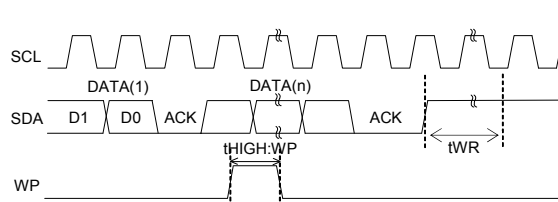


Fig.1-(e) WP timing at write cancel

●Block diagram

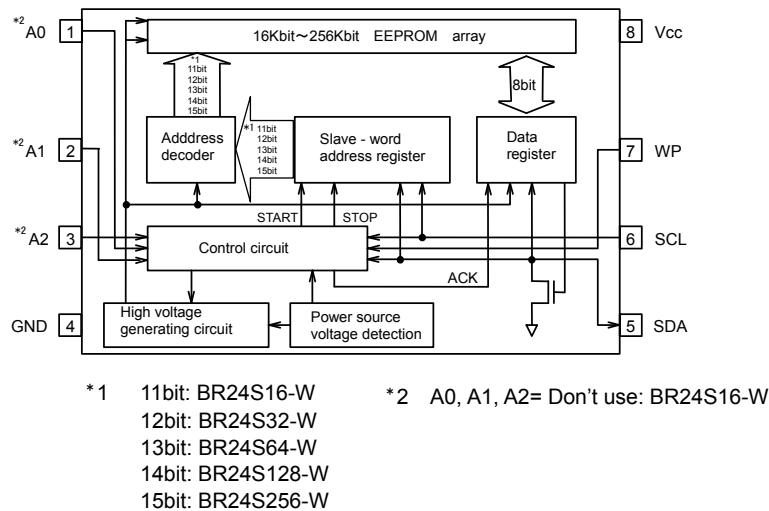
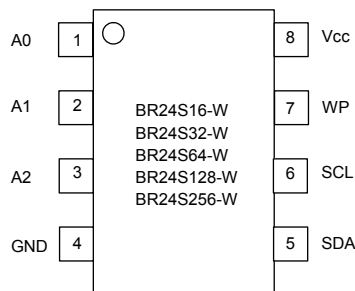


Fig.2 Block diagram

●Pin assignment and description



Terminal name	Input/ Output	Function	
		BR24S16-W	BR24S32/64/128/256-W
A0	Input	Don't use	Slave address setting
A1	Input	Don't use	Slave address setting
A2	Input	Don't use	Slave address setting
GND	-	Reference voltage of all input / output, 0V.	
SDA	Input / Output	Slave and word address, Serial data input serial data output	
SCL	Input	Serial clock input	
WP	Input	Write protect terminal	
Vcc	-	Connect the power source.	

●Characteristic data (The following values are Typ. ones.)

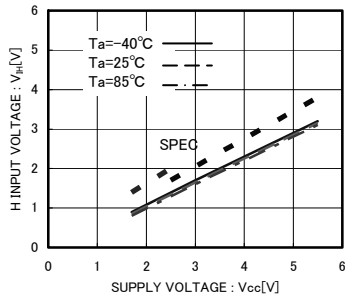


Fig.3 'H' input voltage V_{IH}
(A0,A1,A2,SCL,SDA,WP)

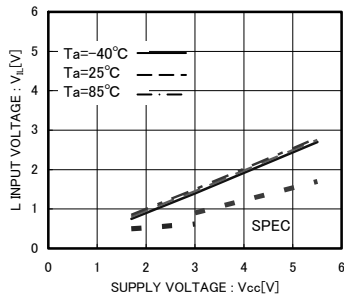


Fig.4 'L' input voltage V_{IL}
(A0,A1,A2,SCL,SDA,WP)

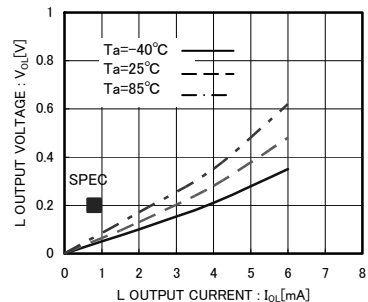


Fig.5 'L' output voltage $V_{OL}-I_{OL}$ ($V_{CC}=1.7V$)

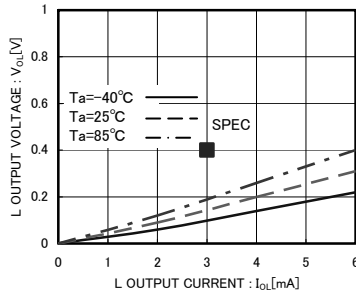


Fig.6 'L' output voltage $V_{OL}-I_{OL}$ ($V_{CC}=2.5V$)

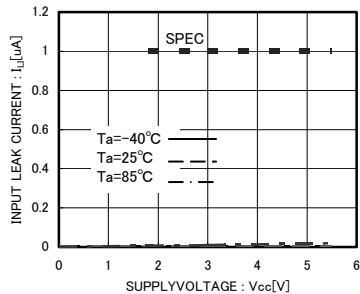


Fig.7 Input leak current I_L
(A0,A1,A2,SCL,WP)

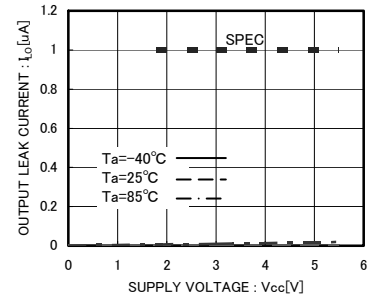


Fig.8 Output leak current I_{LO} (SDA)

●Characteristic data (The following values are Typ. ones.)

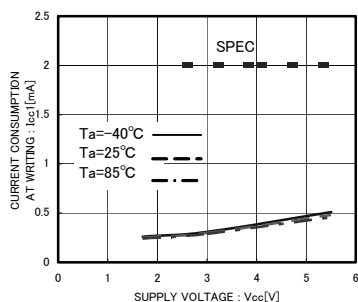


Fig.9 Current consumption at WRITE operation I_{CC1}
($f_{SCL}=400\text{kHz}$ BR24S16/32/64-W)

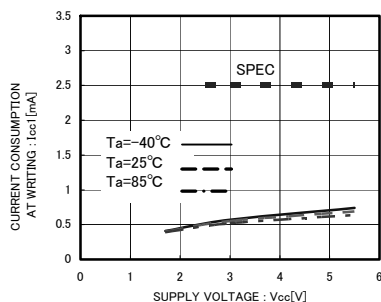


Fig.10 Current consumption at WRITE operation I_{CC1}
($f_{SCL}=400\text{kHz}$ BR24S128/256-W)

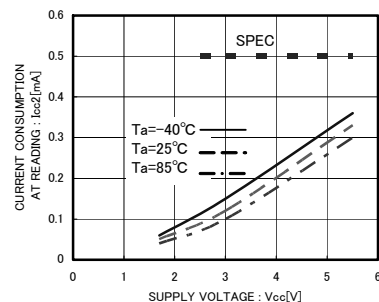


Fig.11 Current consumption at READ operation I_{CC2}
($f_{SCL}=400\text{kHz}$)

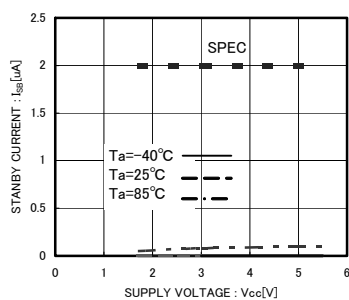


Fig.12 Standby operation I_{SB}

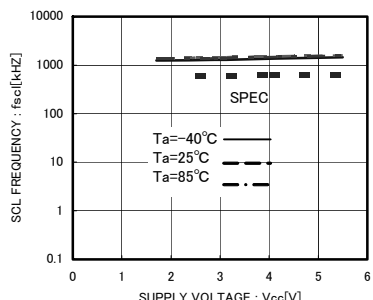


Fig.13 SCL frequency f_{SCL}

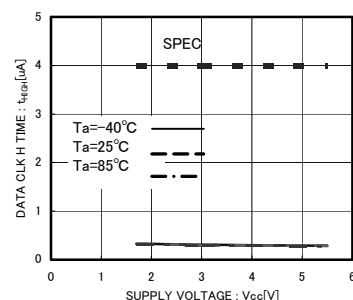


Fig.14 Data clock High Period t_{HIGH}

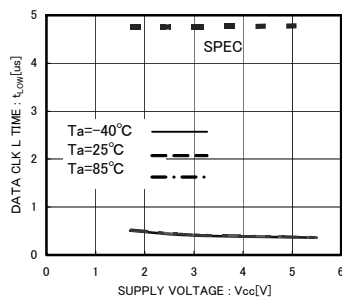


Fig.15 Data clock Low Period t_{LOW}

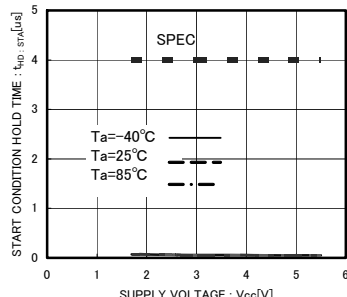


Fig.16 Start Condition Hold Time $t_{HD : STA}$

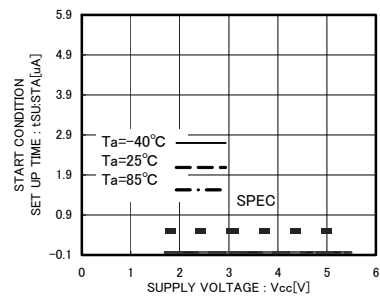


Fig.17 Start Condition Setup Time $t_{SU : STA}$

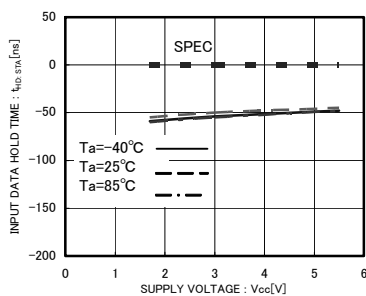


Fig.18 Input Data Hold Time $t_{HD : DAT (HIGH)}$

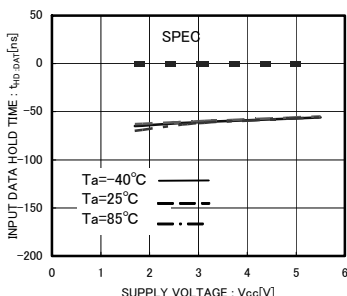


Fig.19 Input Data Hold Time $t_{HD : DAT (LOW)}$

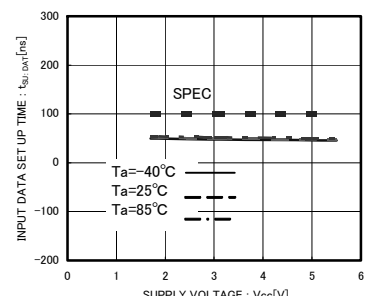


Fig.20 Input Data Setup Time $t_{SU : DAT (HIGH)}$

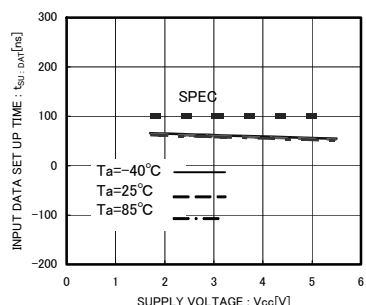


Fig.21 Input Data setup time $t_{SU : DAT (LOW)}$

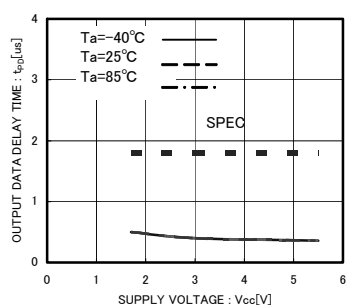


Fig.22 'L' Data output delay time t_{PD0}

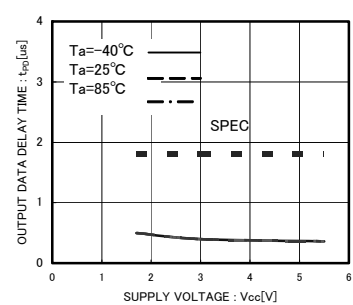


Fig.23 'H' Data output delay time t_{PD1}

●Characteristic data (The following values are Typ. ones.)

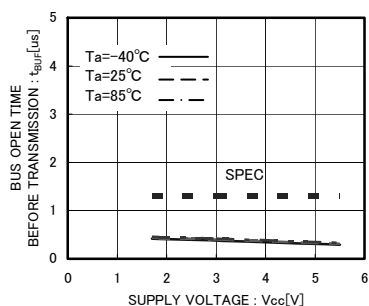


Fig.24 BUS open time before transmission t_{BUF}

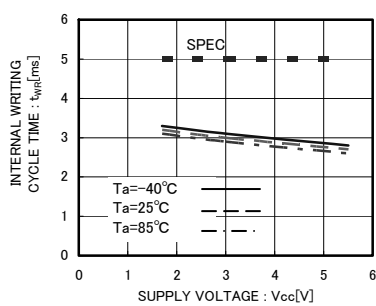


Fig.25 Internal writing cycle time t_{WR}

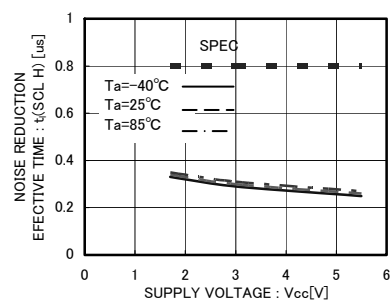


Fig.26 Noise reduction effective time $t_I(SCL H)$

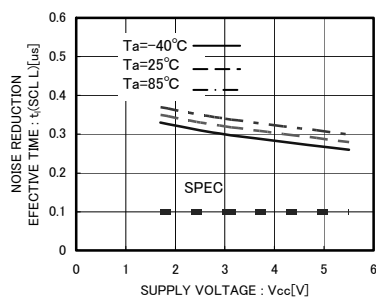


Fig.27 Noise reduction effective time $t_I(SCL L)$

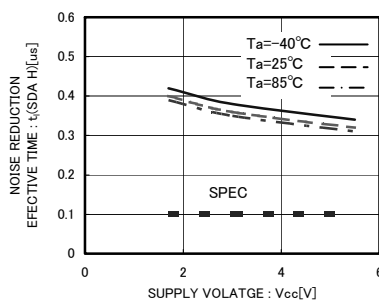


Fig.28 Noise reduction effective time $t_I(SDA H)$

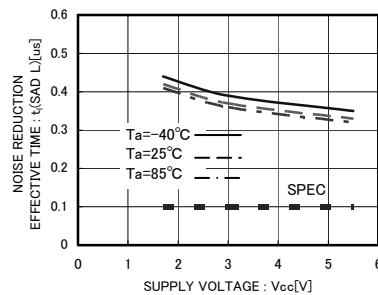


Fig.29 Noise reduction effective time $t_I(SDA L)$

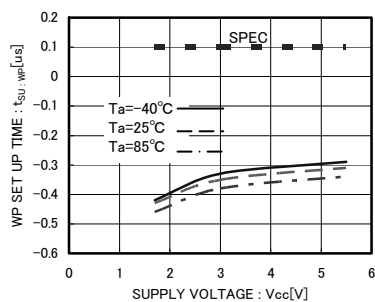


Fig.30 WP setup time $t_{SU:WP}$

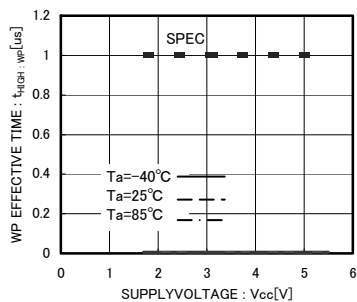


Fig.31 WP effective time $t_{HIGH:WP}$

● I²C BUS communication

○ I²C BUS data communication

I²C BUS data communication starts by start condition input, and ends by stop condition input. Data is always 8bit long, and acknowledge is always required after each byte.

I²C BUS carries out data transmission with plural devices connected by 2 communication lines of serial data (SDA) and serial clock (SCL).

Among devices, there are "master" that generates clock and control communication start and end, and "slave" that is controlled by addresses peculiar to devices.

EEPROM becomes "slave". And the device that outputs data to bus during data communication is called "transmitter", and the device that receives data is called "receiver".

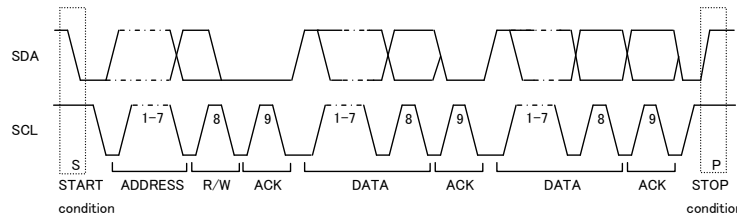


Fig.32 Data transfer timing

○ Start condition (start bit recognition)

- Before executing each command, start condition (start bit) where SDA goes from 'HIGH' down to 'LOW' when SCL is 'HIGH' is necessary.
- This IC always detects whether SDA and SCL are in start condition (start bit) or not, therefore, unless this condition is satisfied, any command is executed.

○ Stop condition (stop bit recognition)

- Each command can be ended by SDA rising from 'LOW' to 'HIGH' when stop condition (stop bit), namely, SCL is 'HIGH'

○ Acknowledge (ACK) signal

- This acknowledge (ACK) signal is a software rule to show whether data transfer has been made normally or not. In master and slave, the device (μ -COM at slave address input of write command, read command, and this IC at data output of read command) at the transmitter (sending) side releases the bus after output of 8bit data.
- The device (this IC at slave address input of write command, read command, and μ -COM at data output of read command) at the receiver (receiving) side sets SDA 'LOW' during 9 clock cycles, and outputs acknowledge signal (ACK signal) showing that it has received the 8bit data.
- This IC, after recognizing start condition and slave address (8bit), outputs acknowledge signal (ACK signal) 'LOW'.
- Each write action outputs acknowledge signal (ACK signal) 'LOW', at receiving 8bit data (word address and write data).
- Each read action outputs 8bit data (read data), and detects acknowledge signal (ACK signal) 'LOW'.
- When acknowledge signal (ACK signal) is detected, and stop condition is not sent from the master (μ -COM) side, this IC continues data output. When acknowledge signal (ACK signal) is not detected, this IC stops data transfer, and recognizes stop condition (stop bit), and ends read action. And this IC gets in standby status.

○ Device addressing

- Output slave address after start condition from master.
- The significant 4 bits of slave address are used for recognizing a device type. The device code of this IC is fixed to '1010'.
- Next slave addresses (A2 A1 A0 --- device address) are for selecting devices, and plural ones can be used on a same bus according to the number of device addresses.
- The most insignificant bit ($R/\overline{W}$ --- READ/ $\overline{WRITE}$) of slave address is used for designating write or read action, and is as shown below.

Setting $R/\overline{W}$ to 0 --- write (setting 0 to word address setting of random read)

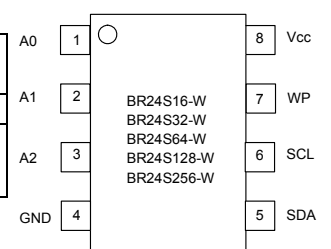
Setting $R/\overline{W}$ to 1 --- read

Type	Slave address							Maximum number of connected buses
BR24S16-W	1	0	1	0	P2	P1	P0 $R/\overline{W}$	1
BR24S32-W, BR24S64-W, BR24S128-W, BR24S256-W	1	0	1	0	A2	A1	A0 $R/\overline{W}$	8

P0~P2 are page select bits.

Note) Up to 1 units of BR24S16-W, and up to 8 units of BR24S32/64/128/256-W can be connected.

Device address is set by 'H' and 'L' of each pin of A0, A1, and A2.



●Write Command

○Write cycle

- Arbitrary data is written to EEPROM. When to write only 1 byte, byte write normally used, and when to write continuous data of 2 bytes or more, simultaneous write is possible by page write cycle. The maximum number of write bytes is specified per device of each capacity.

Up to 64 arbitrary bytes can be written. (In the case of BR24S128/256-W)

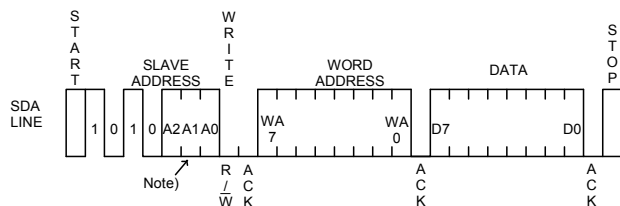
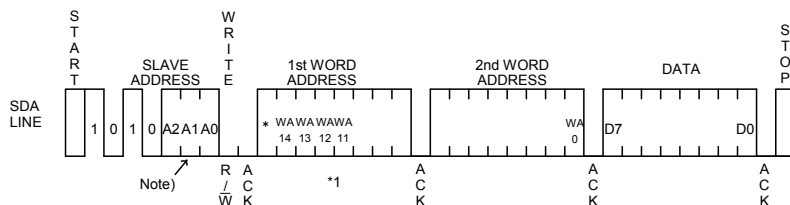


Fig.33 Byte write cycle (BR24S16-W)



*1 As for WA12, BR24S32-W becomes Don't care.
As for WA13, BR24S32/64-W becomes Don't care.
As for WA14, BR24S32/64/128-W becomes Don't care.

Fig.34 Byte write cycle (BR24S32/64/128/256-W)

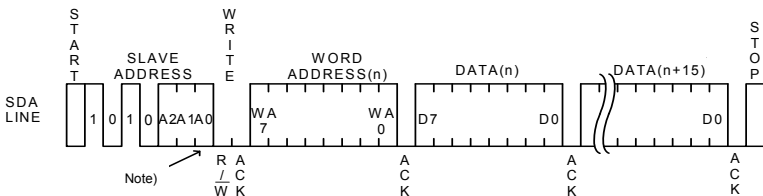
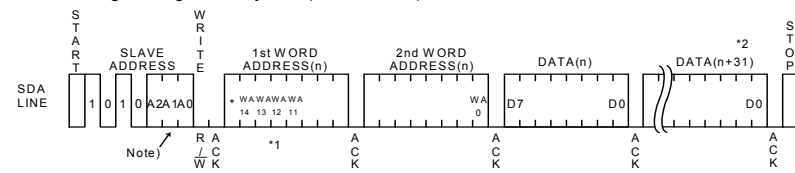


Fig.35 Page write cycle (BR24S16-W)



*1 As for WA12, BR24S32-W becomes Don't care.
As for WA13, BR24S32/64-W becomes Don't care.
As for WA14, BR24S32/64/128-W becomes Don't care.

*2 As for BR24S128/256-W becomes (n+63).

Fig.36 Page write cycle (BR24S32/64/128/256-W)

- Data is written to the address designated by word address (n-th address).
- By issuing stop bit after 8bit data input, write to memory cell inside starts.
- When internal write is started, command is not accepted for tWR (5ms at maximum).
- By page write cycle, the following can be written in bulk: Up to 16 bytes (BR24S16-W)
Up to 32 bytes (BR24S32-W, BR24S64-W)
Up to 64 bytes (BR24S128-W, BR24S256-W)

And when data of the maximum bytes or higher is sent, data from the first byte is overwritten.

(Refer to "Internal address increment of "Notes on page write cycle" in P24/32.)

- As for page write command of BR24S16-W, after page select bit(PS) of slave address is designated arbitrarily, by continuing data input of 2 bytes or more, the address of insignificant 4 bits is incremented internally, and data up to 16 bytes can be written.
- As for page write cycle of BR24S32-W and BR24S64-W, after the significant 7 bits (in the case of BR24S32-W) of word address, or the significant 8 bits (in the case of BR24S64-W) of word address are designated arbitrarily, by continuing data input of 2 bytes or more, the address of insignificant 5 bits is incremented internally, and data up to 32 bytes can be written.
- As for page write cycle of BR24S128-W and BR24S256-W, after the significant 9 bit (in the case of BR24S128-W) of word address, or the significant 10bit (in the case of BR24S256-W) of word address are designated arbitrarily, by continuing data input of 64 bytes or more.

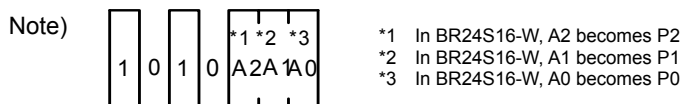
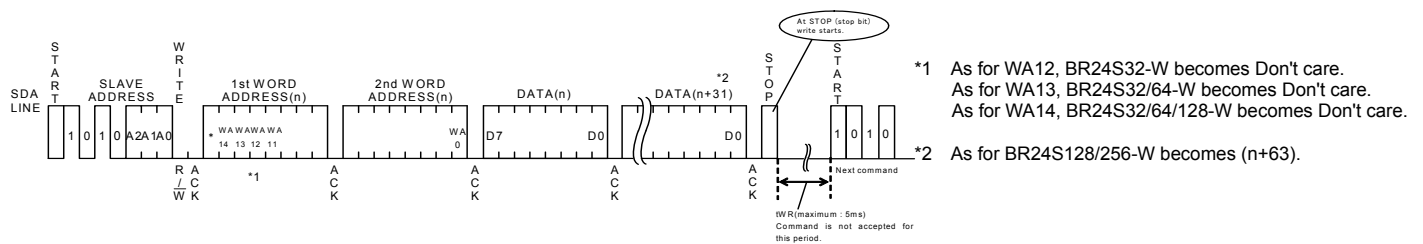
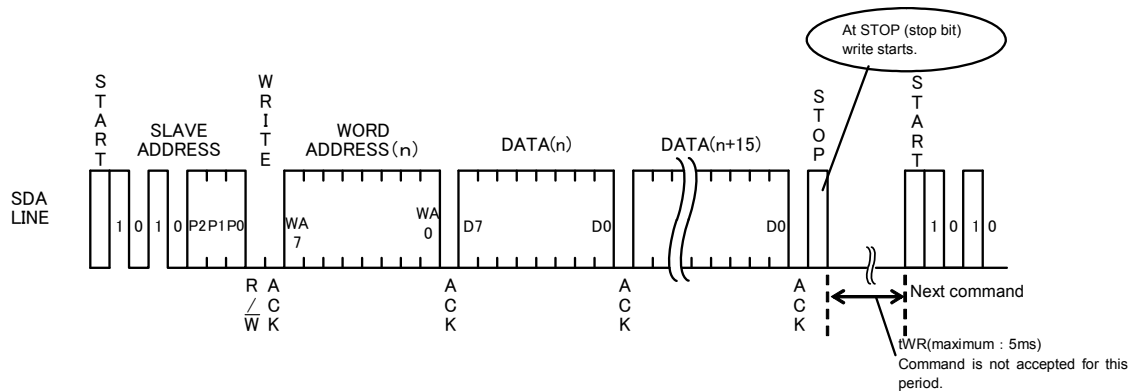


Fig.37 Difference of slave address each type

Notes on write cycle continuous input



Notes on page write cycle

List of numbers of page write

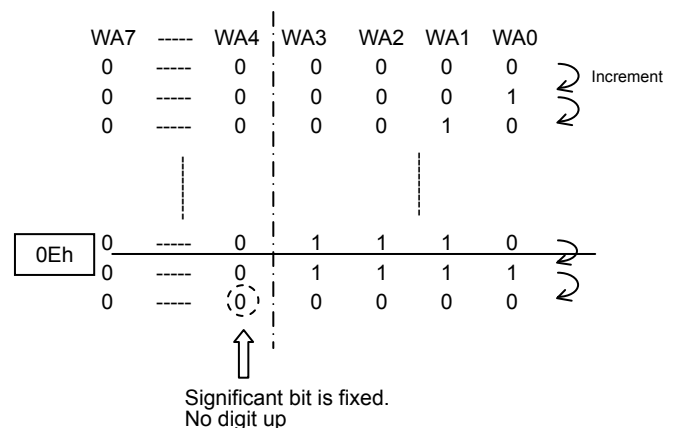
Number of pages	16Byte	32Byte	64Byte
Product number	BR24S16-W	BR24S32-W BR24S64-W	BR24S128-W BR24S256-W

The above numbers are maximum bytes for respective types. Any bytes below these can be written.

In the case of BR24S256-W, 1 page = 64bytes, but the page write cycle write time is 5ms at maximum for 64byte bulk write.

It does not stand 5ms at maximum × 64byte = 320ms(Max.).

Internal address increment Page write mode (in the case of BR24S16-W)



Write protect (WP) terminal

Write protect (WP) function

When WP terminal is set Vcc (H level), data rewrite of all address is prohibited. When it is set GND (L level), data rewrite of all address is enabled. Be sure to connect this terminal to Vcc or GND, or control it to H level or L level. Do not use it open.

At extremely low voltage at power ON/OFF, by setting the WP terminal 'H', mistake write can be prevented.

During tWR, set the WP terminal always to 'L'. If it is set 'H', write is forcibly terminated.

●Read Command

○Read cycle

Data of EEPROM is read. In read cycle, there are random read cycle and current read cycle.

Random read cycle is a command to read data by designating address, and is used generally.

Current read cycle is a command to read data of internal address register without designating address, and is used when to verify just after write cycle. In both the read cycles, sequential read cycle is available, and the next address data can be read in succession.

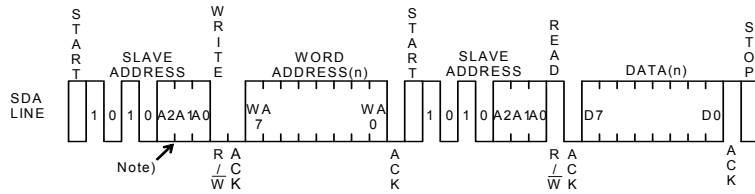


Fig.40 Random read cycle (BR24S16-W)

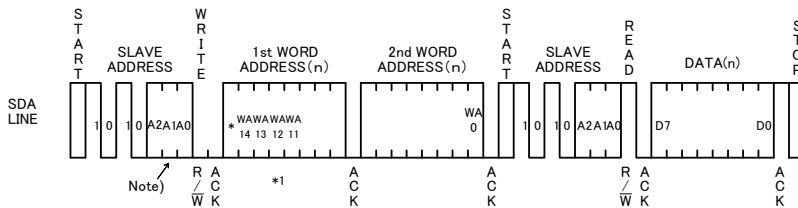


Fig.41 Random read cycle (BR24S32/64/128/256-W)

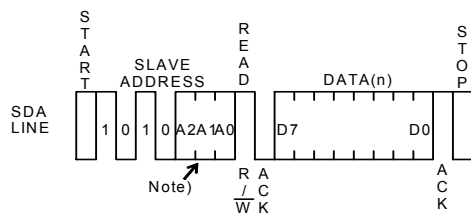


Fig.42 Current read cycle

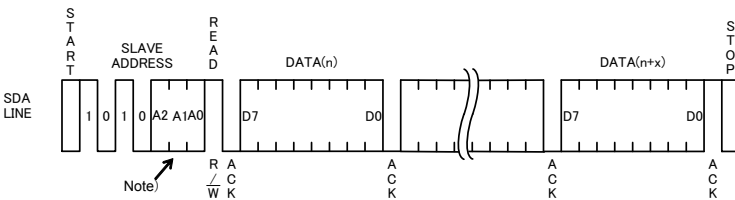
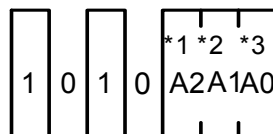


Fig.43 Sequential read cycle (in the case of current read cycle)

- In random read cycle, data of designated word address can be read.
 - When the command just before current read cycle is random read cycle, current read cycle (each including sequential read cycle), data of incremented last read address (n)-th address, i.e., data of the (n+1)-th address is output.
 - When ACK signal 'LOW' after D0 is detected, and stop condition is not sent from master (μ -COM) side, the next address data can be read in succession.
 - Read cycle is ended by stop condition where 'H' is input to ACK signal after D0 and SDA signal is started at SCL signal 'H'.
 - When 'H' is not input to ACK signal after D0, sequential read gets in, and the next data is output.
- Therefore, read command cycle cannot be ended. When to end read command cycle, be sure input stop condition to input 'H' to ACK signal after D0, and to start SDA at SCL signal 'H'.
- Sequential read is ended by stop condition where 'H' is input to ACK signal after arbitrary D0 and SDA is started at SCL signal 'H'.

Note)



- *1 BR24S16-W A2 becomes P2.
- *2 BR24S16-W A1 becomes P1.
- *3 BR24S16-W A0 becomes P0.

Fig.44 Difference of slave address of each type

● Software reset

Software reset is executed when to avoid malfunction after power on, and to reset during command input. Software reset has several kinds, and 3 kinds of them are shown in the figure below. (Refer to Fig.45(a), Fig.45(b), Fig.45(c).) In dummy clock input area, release the SDA bus ('H' by pull up). In dummy clock area, ACK output and read data '0' (both 'L' level) may be output from EEPROM, therefore, if 'H' is input forcibly, output may conflict and over current may flow, leading to instantaneous power failure of system power source or influence upon devices.

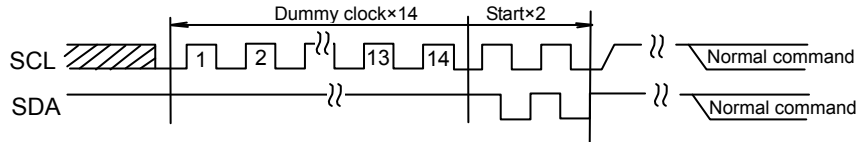


Fig.45-(a) The case of 14 Dummy clock + START + START+ command input

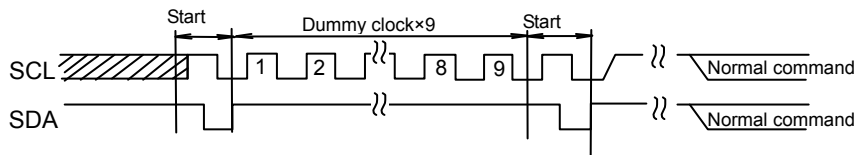


Fig.45-(b) The case of START+9 Dummy clock + START + command input

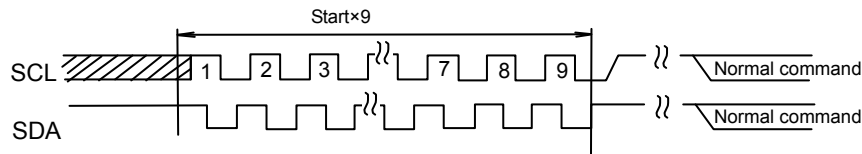


Fig.45-(c) START × 9 + command input

* Start command from START input.

● Acknowledge polling

During internal write, all input commands are ignored, therefore ACK is not sent back. During internal automatic write execution after write cycle input, next command (slave address) is sent, and if the first ACK signal sends back 'L', then it means end of write action, while if it sends back 'H', it means now in writing. By use of acknowledge polling, next command can be executed without waiting for $t_{WR} = 5\text{ms}$.

When to write continuously, $R/\overline{W} = 0$, when to carry out current read cycle after write, slave address $R/\overline{W} = 1$ is sent, and if ACK signal sends back 'L', then execute word address input and data so forth.

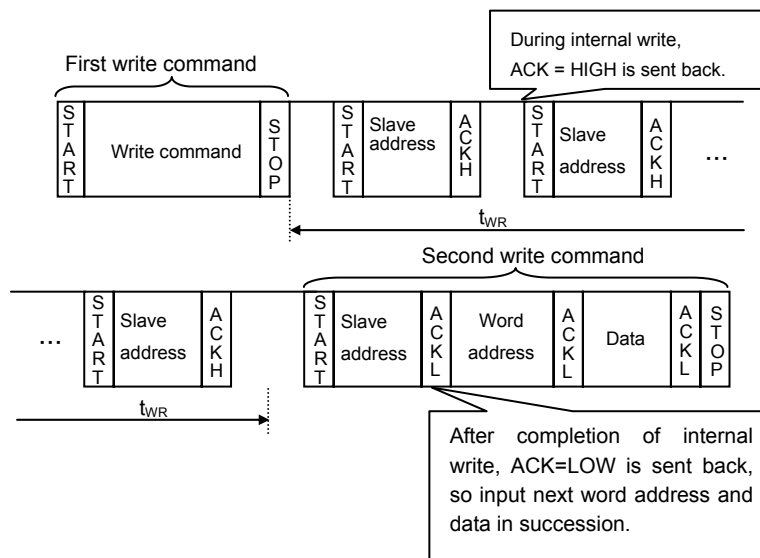


Fig.46 Case to continuously write by acknowledge polling

●WP valid timing (write cancel)

WP is usually fixed to 'H' or 'L', but when WP is used to cancel write cycle and so forth, pay attention to the following WP valid timing. During write cycle execution, in cancel valid area, by setting WP='H', write cycle can be cancelled. In both byte write cycle and page write cycle, the area from the first start condition of command to the rise of clock to taken in D0 of data(in page write cycle, the first byte data) is cancel invalid area.

WP input in this area becomes Don't care. Set the setup time to rise of D0 taken 100ns or more. The area from the rise of SCL to take in D0 to the end of internal automatic write (tWR) is cancel valid area. And, when it is set WP='H' during tWR, write is ended forcibly, data of address under access is not guaranteed, therefore, write it once again.(Refer to Fig.47.) After execution of forced end by WP standby status gets in, so there is no need to wait for tWR (5ms at maximum).

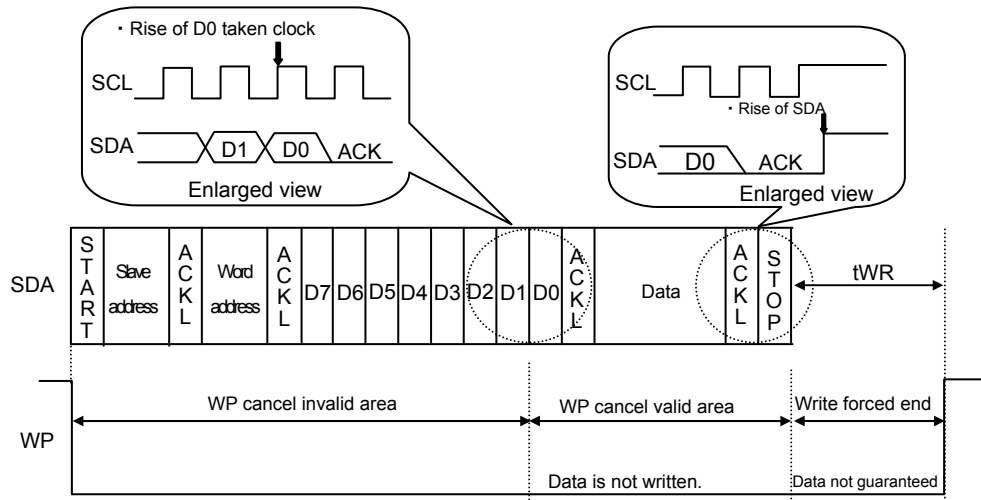


Fig.47 WP valid timing

●Command cancel by start condition and stop condition

During command input, by continuously inputting start condition and stop condition, command can be cancelled. (Refer to Fig. 48.)

However, in ACK output area and during data read, SDA bus may output 'L', and in this case, start condition and stop condition cannot be input, so reset is not available. Therefore, execute software reset. And when command is cancelled by start, stop condition, during random read cycle, sequential read cycle, or current read cycle, internal setting address is not determined, therefore, it is not possible to carry out current read cycle in succession. When to carry out read cycle in succession, carry out random read cycle.

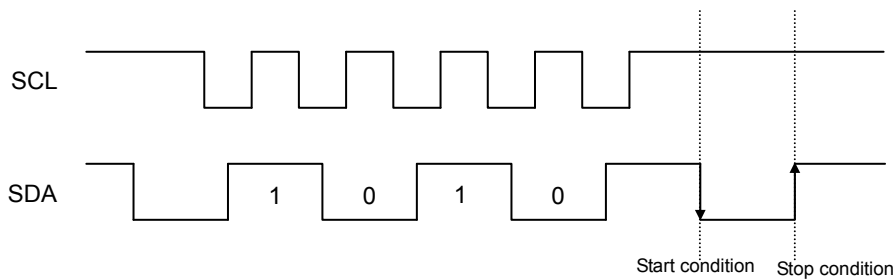


Fig.48 Case of cancel by start, stop condition during slave address input

● I/O peripheral circuit

OPull up resistance of SDA terminal

SDA is NMOS open drain, so requires pull up resistance. As for this resistance value (R_{PU}), select an appropriate value to this resistance value from microcontroller V_{IL} , I_L , and $V_{OL}-I_{OL}$ characteristics of this IC. If R_{PU} is large, action frequency is limited. The smaller the R_{PU} , the larger the consumption current at action.

OMaximum value of R_{PU}

The maximum value of R_{PU} is determined by the following factors.

(1) SDA rise time to be determined by the capacitance (CBUS) of bus line of R_{PU} and SDA should be t_R or below.

And AC timing should be satisfied even when SDA rise time is late.

(2) The bus electric potential (A) to be determined by input leak total (I_L) of device connected to bus output of 'H' to SDA bus and R_{PU} should sufficiently secure the input 'H' level (V_{IH}) of microcontroller and EEPROM including recommended noise margin $0.2V_{CC}$.

$$V_{CC} - I_L R_{PU} - 0.2V_{CC} \geq V_{IH}$$

$$\therefore R_{PU} \leq \frac{0.8V_{CC} - V_{IH}}{I_L}$$

Ex.) When $V_{CC} = 3V$, $I_L = 10\mu A$, $V_{IH} = 0.7V_{CC}$,

from(2)

$$R_{PU} \leq \frac{0.8 \times 3 - 0.7 \times 3}{10 \times 10^{-6}}$$

$$\leq 300 \text{ [k}\Omega\text{]}$$

OMinimum value of R_{PU}

The minimum value of R_{PU} is determined by the following factors.

(1) When IC outputs LOW, it should be satisfied that $V_{OLMAX} = 0.4V$ and $I_{OLMAX} = 3mA$.

$$\frac{V_{CC} - V_{OL}}{R_{PU}} \leq I_{OL}$$

$$\therefore R_{PU} \geq \frac{V_{CC} - V_{OL}}{I_{OL}}$$

(2) $V_{OLMAX} = 0.4V$ should secure the input 'L' level (V_{IL}) of microcontroller and EEPROM including recommended noise margin $0.1V_{CC}$.

$$V_{OLMAX} \leq V_{IL} - 0.1V_{CC}$$

Ex.) When $V_{CC} = 3V$, $V_{OL} = 0.4V$, $I_{OL} = 3mA$, microcontroller, EEPROM $V_{IL} = 0.3V_{CC}$

from(1),

$$R_{PU} \geq \frac{3 - 0.4}{3 \times 10^{-3}}$$

$$\geq 867 \text{ [}\Omega\text{]}$$

And

$$V_{OL} = 0.4 \text{ [V]}$$

$$V_{IL} = 0.3 \times 3$$

$$= 0.9 \text{ [V]}$$

Therefore, the condition (2) is satisfied.

OPull up resistance of SCL terminal

When SCL control is made at CMOS output port, there is no need, but in the case there is timing where SCL becomes 'Hi-Z', add a pull up resistance. As for the pull up resistance, one of several $k\Omega$ ~ several ten $k\Omega$ is recommended in consideration of drive performance of output port of microcontroller.

● A0, A1, A2, WP process

OProcess of device address terminals (A0,A1,A2)

Check whether the set device address coincides with device address input sent from the master side or not, and select one among plural devices connected to a same bus. Connect this terminal to pull up or pull down, or V_{CC} or GND. And, pins (Don't use PIN) not used as device address may be set to any of 'H', 'L', and 'Hi-Z'.

Types with Don't use PIN

BR24S16/F/FJ/FV/FVT/FVM/FVJ/NUX-W A0, A1, A2

OProcess of WP terminal

WP terminal is the terminal that prohibits and permits write in hardware manner. In 'H' status, only READ is available and WRITE of all address is prohibited. In the case of 'L', both are available. In the case of use it as an ROM, it is recommended to connect it to pull up or V_{CC} . In the case to use both READ and WRITE, control WP terminal or connect it to pull down or GND.

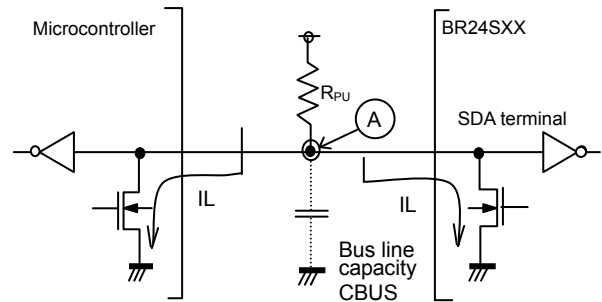


Fig.49 I/O circuit diagram

●Cautions on microcontroller connection

ORs

In I²C BUS, it is recommended that SDA port is of open drain input/output. However, when to use CMOS input / output of tri state to SDA port, insert a series resistance R_s between the pull up resistance R_{PU} and the SDA terminal of EEPROM. This controls over current that occurs when PMOS of the microcontroller and NMOS of EEPROM are turned ON simultaneously. R_s also plays the role of protection of SDA terminal against surge. Therefore, even when SDA port is open drain input/output, R_s can be used.

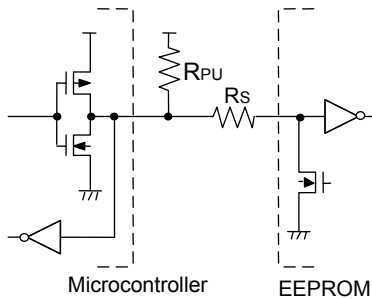


Fig.50 I/O circuit diagram

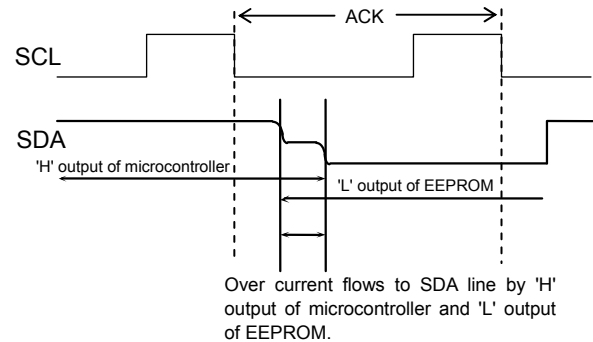


Fig.51 Input/output collision timing

OMaximum value of R_s

The maximum value of R_s is determined by following relations.

- (1) SDA rise time to be determined by the capacity (CBUS) of bus line of R_{PU} and SDA should be t_R or below.
And AC timing should be satisfied even when SDA rise time is late.
- (2) The bus electric potential Φ to be determined by R_{PU} and R_s the moment when EEPROM outputs 'L' to SDA bus should sufficiently secure the input 'L' level (V_{IL}) of microcontroller including recommended noise margin $0.1V_{CC}$.

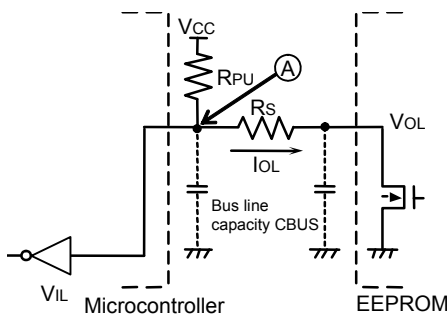


Fig.52 I/O circuit diagram

$$\frac{(V_{CC}-V_{OL}) \times R_s}{R_{PU}+R_s} + V_{OL} + 0.1V_{CC} \leq V_{IL}$$

$$\therefore R_s \leq \frac{V_{IL}-V_{OL}-0.1V_{CC}}{1.1V_{CC}-V_{IL}} \times R_{PU}$$

Example) When $V_{CC}=3V$, $V_{IL}=0.3V_{CC}$, $V_{OL}=0.4V$, $R_{PU}=20k\Omega$,

$$\begin{aligned} \text{from (2), } R_s &\leq \frac{0.3 \times 3 - 0.4 - 0.1 \times 3}{1.1 \times 3 - 0.3 \times 3} \times 20 \times 10^3 \\ &\leq 1.67[k\Omega] \end{aligned}$$

OMaximum value of R_s

The minimum value of R_s is determined by over current at bus collision. When over current flows, noises in power source line, and instantaneous power failure of power source may occur. When allowable over current is defined as I , the following relation must be satisfied. Determine the allowable current in consideration of impedance of power source line in set and so forth. Set the over current to EEPROM 10mA or below.

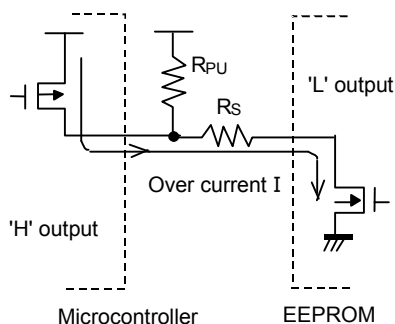


Fig.53 I/O circuit diagram

$$\frac{V_{CC}}{R_s} \leq I$$

$$\therefore R_s \geq \frac{V_{CC}}{I}$$

Example) When $V_{CC}=3V$, $I=10mA$

$$\begin{aligned} R_s &\geq \frac{3}{10 \times 10^{-3}} \\ &\geq 300[\Omega] \end{aligned}$$

●I²C BUS input / output circuit

○Input (A0, A1, A2, SCL, WP)

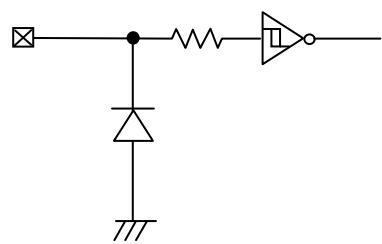


Fig.54 Input pin circuit diagram

○Input/Output (SDA)

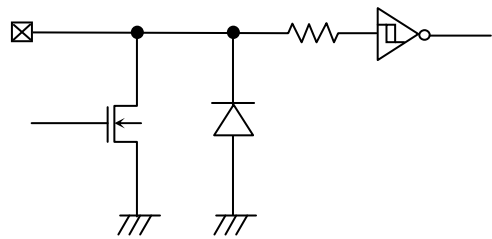
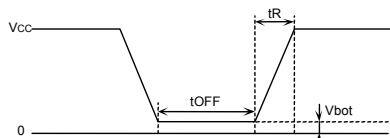


Fig.55 Input /output pin circuit diagram

●Notes on power ON

At power on, in IC internal circuit and set, Vcc rises through unstable low voltage area, and IC inside is not completely reset, and malfunction may occur. To prevent this, functions of POR circuit and LVCC circuit are equipped. To assure the action, observe the following condition at power on.

1. Set SDA = 'H' and SCL = 'L' or 'H'
2. Start power source so as to satisfy the recommended conditions of tR, tOFF, and Vbot for operating POR circuit.



Recommended conditions of tR, tOFF, Vbot

tR	tOFF	Vbot
10ms or below	10ms or longer	0.3V or below
100ms or below	10ms or longer	0.2V or below

3. Set SDA and SCL so as not to become 'Hi-Z'.

Fig.56 Rise waveform diagram

When the above conditions 1 and 2 cannot be observed, take the following countermeasures.

- a) In the case when the above conditions 1 cannot be observed. When SDA becomes 'L' at power on .
→Control SCL and SDA as shown below, to make SCL and SDA, 'H' and 'H'.

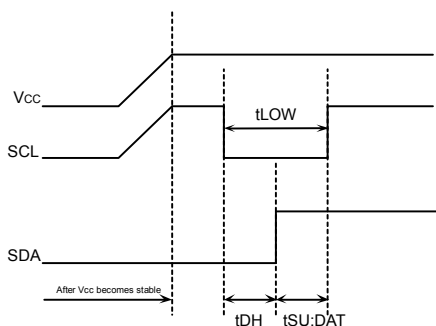


Fig.57 When SCL='H' and SDA='L'

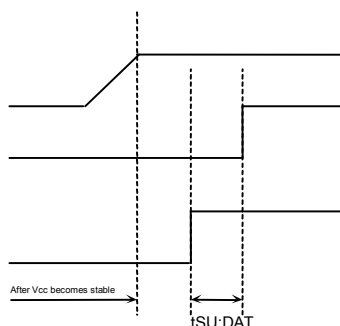


Fig.58 When SCL='H' and SDA='L'

- b) In the case when the above condition 2 cannot be observed.
→After power source becomes stable, execute software reset(P26).
- c) In the case when the above conditions 1 and 2 cannot be observed.
→Carry out a), and then carry out b).

●Low voltage malfunction prevention function

LVCC circuit prevents data rewrite action at low power, and prevents wrong write.

At LVCC voltage (Typ. =1.2V) or below, it prevent data rewrite.

●Vcc noise countermeasures

○Bypass capacitor

When noise or surge gets in the power source line, malfunction may occur, therefore, for removing these, it is recommended to attach a by pass capacitor (0.1μF) between IC Vcc and GND. At that moment, attach it as close to IC as possible.

And, it is also recommended to attach a bypass capacitor between board Vcc and GND.

●Cautions on use

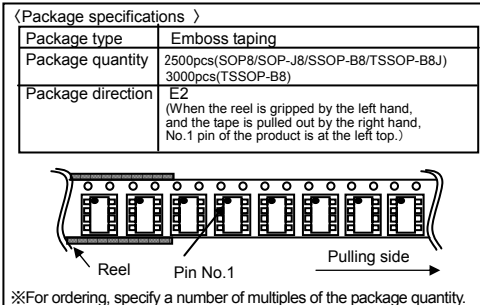
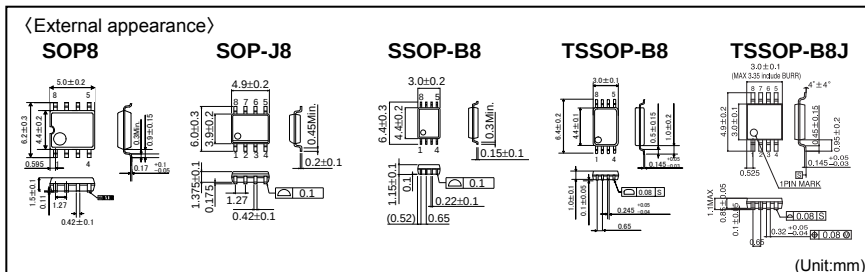
- (1)Described numeric values and data are design representative values, and the values are not guaranteed.
- (2)We believe that application circuit examples are recommendable, however, in actual use, confirm characteristics further sufficiently. In the case of use by changing the fixed number of external parts, make your decision with sufficient margin in consideration of static characteristics and transition characteristics and fluctuations of external parts and our LSI.
- (3)Absolute maximum ratings
If the absolute maximum ratings such as impressed voltage and action temperature range and so forth are exceeded, LSI may be destructed. Do not impress voltage and temperature exceeding the absolute maximum ratings. In the case of fear exceeding the absolute maximum ratings, take physical safety countermeasures such as fuses, and see to it that conditions exceeding the absolute maximum ratings should not be impressed to LSI.
- (4)GND electric potential
Set the voltage of GND terminal lowest at any action condition. Make sure that each terminal voltage is lower than that of GND terminal.
- (5)Terminal design
In consideration of permissible loss in actual use condition, carry out heat design with sufficient margin.
- (6)Terminal to terminal shortcircuit and wrong packaging
When to package LSI onto a board, pay sufficient attention to LSI direction and displacement. Wrong packaging may destruct LSI. And in the case of shortcircuit between LSI terminals and terminals and power source, terminal and GND owing to foreign matter, LSI may be destructed.
- (7)Use in a strong electromagnetic field may cause malfunction, therefore, evaluate design sufficiently.

● Selection of order type

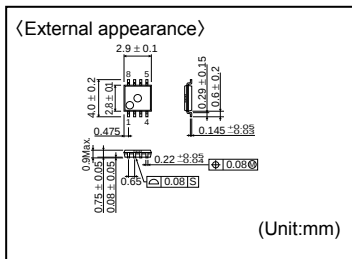
B R	2 4	S	2 5 6	F — W	E 2
ROHM type name	BUS type 24 : I ² C	Operating temperature L: -40°C ~ +85°C S: -40°C ~ +85°C	Capacity 01=1K 16=16K 02=2K 32=32K 04=4K 64=64K 08=8K 128=128K 256=256K	Package F: SOP8 FJ: SOP-J8 FV: SSOP-B8 FVT: TSSOP-B8 FVM: MSOP8 FVJ: TSSOP-B8J NUX: VSON008X2030	Double cell Package specifications E2 : reel shape emboss taping TR : reel shape emboss taping
● Package specifications					

● Package specifications

SOP8/SOP-J8/SSOP-B/TSSOP-B8/TSSOP-B8J

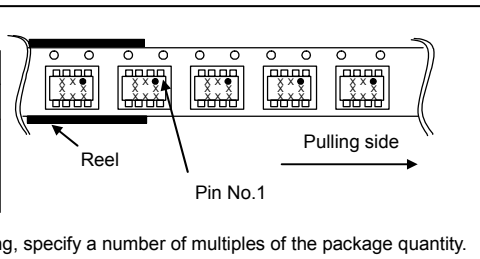


MSOP8

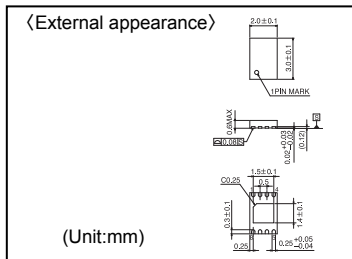


〈Package specifications〉

Package type	Emboss taping
Package quantity	3000pcs
Package direction	TR (When the reel is gripped by the left hand, and the tape is pulled out by the right hand, No.1 pin of the product is at the right top.)

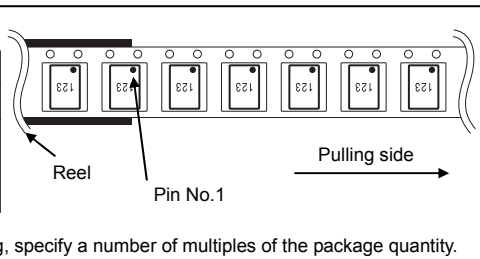


VSON008X2030



〈Package specifications〉

Package type	Emboss taping
Package quantity	4000pcs
Package direction	TR (When the reel is gripped by the left hand, and the tape is pulled out by the right hand, No.1 pin of the product is at the right top.)



- The contents described herein are correct as of September, 2008
- The contents described herein are subject to change without notice. For updates of the latest information, please contact and confirm with ROHM CO.,LTD.
- Any part of this application note must not be duplicated or copied without our permission.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams and information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by ROHM CO., LTD. is granted to any such buyer.
- The products described herein utilize silicon as the main material.
- The products described herein are not designed to be X ray proof.

The products listed in this catalog are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys). Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

Contact us for further information about the products.

Excellence in Electronics

ROHM

ROHM CO., LTD.

21 Saini Mizosaki-cho, Ukyo-ku, Kyoto
615-8585, Japan
TEL: +81-75-311-2121 FAX: +81-75-315-0172
URL: <http://www.rohm.com>

Published by
KTC LSI Development Headquarters
LSI Business Promotion Group

San Diego
Atlanta
Boston
Chicago
Dallas
Denver
Detroit
Nashville
Mexico
Düsseldorf
Munich
Stuttgart
France
United Kingdom
Denmark
Espoo
Salto
Oulu
Barcelona
Hungary
Poland
Russia
Seoul
Masan
Dalian
Beijing

TEL: +1-858-625-3630
TEL: +1-770-754-5972
TEL: +1-978-371-0382
TEL: +1-847-368-1006
TEL: +1-469-287-5366
TEL: +1-303-708-0908
TEL: +1-248-348-9920
TEL: +1-615-620-6700
TEL: +52-33-3123-2001
TEL: +49-2154-9210
TEL: +49-8999-216168
TEL: +49-711-7272-370
TEL: +33-1-5697-3060
TEL: +44-1-908-306700
TEL: +45-3694-4739
TEL: +358-9725-54491
TEL: +358-2-7332234
TEL: +358-8-5372930
TEL: +34-9375-24320
TEL: +36-1-4719338
TEL: +48-22-5757213
TEL: +7-495-739-41-74
TEL: +82-2-8182-700
TEL: +82-55-240-6234
TEL: +86-411-8230-8549
TEL: +86-10-8525-2483

FAX: +1-858-625-3670
FAX: +1-770-754-0691
FAX: +1-928-438-7164
FAX: +1-847-368-1008
FAX: +1-469-362-7973
FAX: +1-303-708-0858
FAX: +1-248-348-9942
FAX: +1-615-620-6702
FAX: +52-33-3123-2002
FAX: +49-2154-921400
FAX: +49-8999-216176
FAX: +49-711-7272-3720
FAX: +33-1-5697-3080
FAX: +44-1-908-235788
FAX: +45-3694-4789
FAX: +358-9-7255-4499
FAX: +358-2-7332237
FAX: +358-8-5372931
FAX: +34-9375-24410
FAX: +36-1-4719339
FAX: +48-22-5757001
FAX: +7-495-739-41-74
FAX: +82-2-8182-715
FAX: +82-55-240-6236
FAX: +86-411-8230-8537
FAX: +86-10-8525-2489

Tianjin
Shanghai
Hangzhou
Nanjing
Ningbo
Qingdao
Suzhou
Wuxi
Shenzhen
Dongguan
Fuzhou
Guangzhou
Huizhou
Xiamen
Zhuhai
Hong Kong
Taipei
Kaohsiung
Singapore
Philippines
Thailand
Kuala Lumpur
Penang
Kyoto
Yokohama

TEL: +86-22-23029181
TEL: +86-21-6279-2727
TEL: +86-571-87658072
TEL: +86-25-8689-0015
TEL: +86-574-87654201
TEL: +86-532-5779-312
TEL: +86-512-6807-1300
TEL: +86-510-82702693
TEL: +86-755-8307-3008
TEL: +86-769-8393-3320
TEL: +86-591-8801-8698
TEL: +86-752-205-1054
TEL: +86-20-3878-8100
TEL: +86-752-205-1059
TEL: +86-592-238-5705
TEL: +86-756-3232-480
TEL: +852-2-740-6262
TEL: +886-2-2500-6956
TEL: +886-7-237-0881
TEL: +65-6332-2322
TEL: +63-2-807-6872
TEL: +66-2-254-4890
TEL: +60-3-7958-8355
TEL: +60-4-2286453
TEL: +81-75-365-1218
TEL: +81-45-476-2290

FAX: +86-22-23029183
FAX: +86-21-6247-2066
FAX: +86-571-87658071
FAX: +86-25-8689-0393
FAX: +86-574-87654208
FAX: +86-532-5779-653
FAX: +86-512-6807-2300
FAX: +86-510-82702992
FAX: +86-755-8307-3003
FAX: +86-769-8398-4140
FAX: +86-591-8801-8690
FAX: +86-20-3825-5965
FAX: +86-752-205-1059
FAX: +86-592-239-8380
FAX: +86-756-3232-460
FAX: +852-2-375-8971
FAX: +886-2-2503-2869
FAX: +886-7-238-7332
FAX: +65-6332-5662
FAX: +63-2-809-1422
FAX: +66-2-256-6334
FAX: +60-3-7958-8377
FAX: +60-4-2286452
FAX: +81-75-365-1228
FAX: +81-45-476-2295

Catalog No.08T504A '08.9 ROHM ©

Notes

No copying or reproduction of this document, in part or in whole, is permitted without the consent of ROHM Co.,Ltd.

The content specified herein is subject to change for improvement without notice.

The content specified herein is for the purpose of introducing ROHM's products (hereinafter "Products"). If you wish to use any such Product, please be sure to refer to the specifications, which can be obtained from ROHM upon request.

Examples of application circuits, circuit constants and any other information contained herein illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

Great care was taken in ensuring the accuracy of the information specified in this document. However, should you incur any damage arising from any inaccuracy or misprint of such information, ROHM shall bear no responsibility for such damage.

The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM and other parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the use of such technical information.

The Products specified in this document are intended to be used with general-use electronic equipment or devices (such as audio visual equipment, office-automation equipment, communication devices, electronic appliances and amusement devices).

The Products specified in this document are not designed to be radiation tolerant.

While ROHM always makes efforts to enhance the quality and reliability of its Products, a Product may fail or malfunction for a variety of reasons.

Please be sure to implement in your equipment using the Products safety measures to guard against the possibility of physical injury, fire or any other damage caused in the event of the failure of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHM shall bear no responsibility whatsoever for your use of any Product outside of the prescribed scope or not in accordance with the instruction manual.

The Products are not designed or manufactured to be used with any equipment, device or system which requires an extremely high level of reliability the failure or malfunction of which may result in a direct threat to human life or create a risk of human injury (such as a medical instrument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel-controller or other safety device). ROHM shall bear no responsibility in any way for use of any of the Products for the above special purposes. If a Product is intended to be used for any such special purpose, please contact a ROHM sales representative before purchasing.

If you intend to export or ship overseas any Product or technology specified herein that may be controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to obtain a license or permit under the Law.



Thank you for your accessing to ROHM product informations.
More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

<http://www.rohm.com/contact/>